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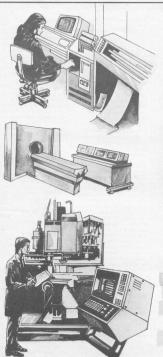
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COMPUTER-SCOPE-1

by B y Linden

To help those many people whose workshop includes a computer but not an oscilloscope, this article presents a drive unit that enables the computer to be used as an oscilloscope.



The idea of using a computer as an oscilloscope is based on the fact that it already has a viewing screen and that it can cope with graphics. All that is required, therefore, is a unit that stores the signal to be measured in a memory, after which the computer can read the memory and display the data on the monitor.

play the data on the monitor.

The article will be in two parts: this month the general layout and the complete circuit will be discussed, while part 2 will deal with the construction and the alignment.

Block diagram

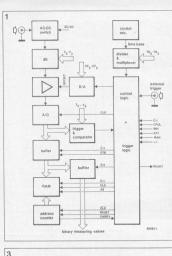
The first section of the unit, i.e., the AC-DC switch, attenuator, and amplifier, consists of analogue circuits, although the first two are controlled by binary signals. An off-set may be added to the amplifier via a digital-to-analogue converter.

The incoming signal is then digitized, after which a fast analogue-todigital converter translates the samples into 7-bit data words that are

stored in a random-access memory via a buffer stage.

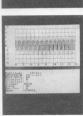
Was a Dimer sage.

The output of the A-D converter is also applied to a trigger and comparator. The latter compares the instance of the compares the com











takes place

The memory consists of two parts, each of 256 bytes. The first part holds 256 pre-trigger measuring points. and the second 256 post-trigger measuring points. A comprehensive address ensures that writing to, and reading from, the memory takes place in the correct sequence. Sixteen different time bases, derived

from a crystal oscillator, are provided. Communication between the drive unit and the computer is effected via

two 8-bit I-O buses: this enables most computers to be used. The computerscope is controlled via software. A menu-type layout gives

the user the possibility of setting all measuring parameters wit only a few

Circuit diagram

page 2

The input is at the centre of Fig. 2 and is connected direct to the AC-DC switch which is formed by capacitor C4 shunted by DIL relay Re1. The switch is followed by the attenuator, which consists of two parts: the first can be arranged to attenuate by a factor 1, 2, or 5, and the second by 1, 10, or 100. The total attenuation is set from the computer by means of multiplexers IC23 and IC24 Both IC23a and IC23b are controlled via lines Vo and Vi, while the multiplexers in IC24 are switched via lines V2 and V3 In this manner the sensitivity can be set between 10 mV/div and 5 V/div.

At the input of the first divider relays instead of multiplexers are used A-D converter. The computer sends

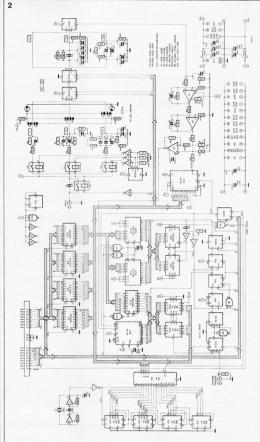
because of the maximum allowable voltage here. Diodes D1 to D8 incl. protect the inputs against too high voltages

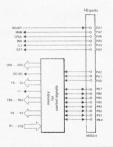
A variety of fixed and variable capacitors in the attenuator sections provide compensation when squarewave signals are processed.

The signal at the output of the second attenuator has a maximum value of 80 mVpp. It is then raised to 2 Vpp by amplifiers A1, A2, and A3, to give a signal that can be processed by the A-D converter at the highest possible resolution.

An off-set is added to the signal in As to enable a vertical shift across the monitor screen. The off-set is provided by a D-A converter, which is housed in IC11 together with the fast

Fig. 3. The RAM firet is used for and the second for storing 256 ie to he trans.





twoon the drive

the off-set data to the D-A converter via lines QFs to QFs incl. The standard value of the off-set is 1 V when the sample lies exactly within the range of the A-D converter (bear in mind that the converter cannot process negative values). Only seven of the ten bits available at the D-A converter are used here which hecause of the graphics resolution of the computers used is more than enough

The output signal of A3 is then applied to a fast A-D converter, which contains a separate comparator for each digital level, i.e. 256 in all. The conversion time is, therefore, only 26.3 ns (corresponding to a frequency of 38 MHz). The highest clock used is 8 MHz, resulting in 8 samples per period at an input signal of 1 MHz

Because of the arrangement of the system, only 7 bits are used, which is sufficient for an accurate display. The eighth bit is used for storing the trigger data. The reference voltage for the A-D and D-A converters is generated by the IC itself. The only external component is capacitor Cso.

The memory section also needs fast ICs, and in the present circuit Type IMS1420 was chosen. This is a RAM with an access time of 45 ns and a capacity of 4 K x 4 bit. Two of these ICs. IC13 and IC14, are connected in parallel to give a width of 8 bits. The data lines of the RAMs are connected with the outputs of the A-D converter via buffer IC12 Of the total memory capacity only 512 bytes are used for data storage; the remainder is available for possible later exten-

The digitizing and storing of the samples is taken care of by the clock provided by the time base. Operation of the A-D converter is commenced at the trailing edge of the clock pulse, and at the same time the address counter of the RAMs is increased by 1

The random-access memory consists of two pages: page 1 contains address 666 to 6FF, and page 2, addresses 100 to IFF. In the absence of a trigger signal, page 1 is written to. As soon as a trigger arives, the eighth bit of the relevant byte goes high, when writing is transferred to nage 2-see Fig. 3. Once this page is full writing to the memory stops, and the computer is advised that writing is completed by the READY signal. In this way, there are always 256 pretrigger and 256 post-trigger sampling points. After the computer has read the memory, the next writing cycle can be started. As long as there is old information on page 1. triggering is prevented for 256 clock pulses by signal INH. This is calculated by the computer from the state of the time base.

The time base (at the left of Fig. 2) consists of crystal oscillator N1-N2. which is followed by a number of :2 and :5 dividers. IC2 to IC4 incl. The computer connects one of the outputs of the time base to the CLK line of the system via multiplexer ICs. Latches IC7 to IC10 are provided for the exchange of signals between the drive unit and the computer. Circuits IC7 to IC9 serve to store data which are sent by the computer to the drive unit via PBo to PBr incl. PAo. PAs, and PA2 are used as write signals for the three ICs.

Circuits IC15 and IC16 form an 8-bit comparator for the trigger signal, which is provided (in binary form) by The connections between the drive

the computer. As soon as the level of the input signal exceeds that of the trigger, the level at the >O output of ICss (pin 5) changes state. The edge of this pulse also indicates whether the input signal exceeded the trigger in a positive or in a negative conco

The output signal of the comparator is applied to a dual four-channel multipleyer IC .. The first part of this stage enables a choice to be made between the >O output of the comparator and the external trigger input with the aid of the EXT signal. The second section. IC17b. is used to choose between the output of the first multiplexer and the inverted output signal, that is, between triggering at the leading or at the trailing edge of the input signal.

The trigger signal is then fed to bistables FF1 and FF2 where it is combined with the CLK and INH signals. Bistable FF2 also provides the eighth data bit for the RAMs: as soon as the circuit is triggered, its output goes high. The eighth data bit is also clocked in bistable FF3, after which it is used as ninth address bit for the memory via multiplexer ICan. During reading, the circuit is switched via ICon to the INH signal as ninth address line, whereas during writing, the output of FF3 is used for this purpose.

When the ninth address bit becomes logic 1, the address counter is reset via network Rs-Cs.

Control signals

unit and the computer are shown in Fig 4 A total of 17 port lines are used: PAs to PA: PRs to PR; and

gering via the keyboard. Bistable FF2 is then set via No which gate ensures that the MAN signal and the CLK eignal in the drive unit are cun-

CPIII, is the clock provided by the computer for reading the RAMs (is

The INH signal prevents triggering of the givenit via histable FF, until the RAM has been read completely by

the computer The computer uses the C/I signal to determine whether the RAM is being written to by the drive unit or is being read by the computer Clogic n - reading)

A logic 1 on the EXT line actuates the external trigger input.

Lines OFe to OFe carry the off-set voltage that is added to the input signal via the D-A converter. The standard value should be 1000000 or ØFFFFFF to give an off-set voltage of

A logic 1 on the AC-DC line causes relay Re. to be energized so that an components in the input signal are Signal MEN anables manual trig-

The data on the Te to Te lines detersignal the value should be set to evactly half the signal level that is 1888888 because of the standard off-

set of 1 V (Ts = MSB). The + /- line enables the computer to choose between triggering at a either in a positive or in a negative

The READY signal indicates to the computer that writing into the RAM has been completed and that the reading process can begin. The internal clock signal is switched off at

that instant Lines TBs to TB; serve to choose the required time hase via IC. A value of 0000 corresponds to 1 mV/div. and 1111 corresponds to 100 mV/div (TB1 = MSB)

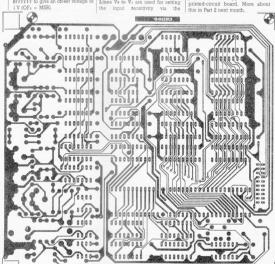
Lines Ve to Va are used for setting



A value of 8888 gives a sensitivity of 10 mV/div while 1010 gives a sensitivity of 5 V/div

Data lines D. to D. incl. are used for transporting the hinary values from the drive unit to the computer (Dr. = MSR) Line Day carries the trigger

This information makes it nossible to write a cuitable program for the computerscope. In many cases that will not be necessary however because a complete program listing for the RRC the Flectron the Commodore C64, and, very likely, MSX computers will be supplied with the printed-circuit board. More about



AIR DEFENCE SYSTEMS FOR COUNTRIES AND CONTINENTS

by John Nicholls CEng. MIERE*

Air provides the breath of human life and the enace it occupies around the alohe has become the dominant "play volume" in man's defence of his kingdom. The grmed forces meet varying threats The primary concern of navies is high and low flying attack weapons. armies have to contend with strike aircraft and missiles while air forces are required to intercent hombers and fighters and eliminate all threats that exist in the gir space To maintain viailance in times of peace and to meet the threats of insurgents in times of war it is vital that all the resources of the armed forces are co-ordinated. Co-ordination is important not only for the air battle but for the safe operation of civil aircraft and requires close co-operation between the defence organizations and civil aviation authorities. An air defence system provides this co-ordination. It is able to detect recognize and monitor information on objects in the air space. It can provide the command and control of interceptor aircraft, the dissemination of target information to field batteries of auns and missiles, and it can provide the com-

for decisions to be made. Modular advantages

mand with a display of a

and sometimes of the sur-

face as well. This includes

all information necessary

recognized air picture

Traditionally, only highly industrialized countries have been able to benefit from large scale air defence systems. Each system would be custom designed resulting in ex-



A typical command and control centre scenario (top) and manned plot reporting stations (bottom), part of the air defence facility at Plessey Radar which is used for demonstration purposes.



pensive and specialized solutions. Analysis has shown that common functions exist in all the elements of air defence systems around the world and it is this that, for instance, Plessey Radar has capitalized on with its air space management products.

The result is a base of hardware and software models, which include offand on-line maintenance aids able to be configured at low cost into virtually any size or variety of air defence system by the addition of customer specific facilities. proach has additional advantages. Rigorous specifications and methodologies can be applied and the modules subjected to thorough inservice use. It also makes the transfer of technology more amenable and simplifies local maintenance.

The modular design ap-

a number of such systems installed and an operational development and demonstration air defence facility at its systems head-quarters. It is now feasible for any notion to have an air defence system that

precisely meets its needs and is aflordable — both initially and throughout the life of the system. The next few years should see a large number being installed and integrated on an international scale.

The air picture

The first requirement of an air defence system is to detect the targets. This can be done passively with electronic sensor maggirement (ESM) aquinment to detect guidio radio frequency and infrared emission. It can also be done with active concore such as radar and laser equipment and of course that original sensor, the eve to report visual sightings. All the information from these sensors whether they be static or mobile on the land at sea, or in the air. is processed by reporting posts. The data provided by reporting posts range from crude directional bearings to accurate recognition of the targets along with positional coordinates.

From the reporting posts. the data are transmitted for processing at a control report post. Here the data are combined with known information, such as civil aircraft flight plans and information from secondary surveillance radar to provide a track database whose accuracy and completeness determines the quality of the air defence system. Operators at display consoles in the control repor-

ting post use this track information to select their targets, to control fighter aircraft on their interception missions using airground-air radios, or to provide targeting information to SAM (surface-to-

air missles) and gun weopan sites. The information is also fed to an air operations centre where again it is combined with inputs from other control reporting posts, processed with multi-sensor algorithms, and displayed as a recognized air picture for the day the sensors with each target having a unique track identity.

Defensive network

At the gir operations centre other information is also shown on consoles and large screen displays to enable the command to plan the tactical and strategic air battle. Details of the status and availability of aircraft auns and missiles are available along with mission designations and the logistic situation from national and allied forces The remaining task of the air defence system is to pass the recognized air picture to a central joint operations centre Here a totally integrated view can be obtained by combining the information from the air operations centre or centres with similar inputs from navy and army systems to give a complete recognized air and surface picture of the country's defensive

network.
The command and control aspects of an air defence system will vary, depending on factors such as the size of the country, the volume of air space to be stelled before management organization. There are three fundamental methods of meeting the requirements. First, command and control can be enturinged.

requirements.

First, command and control can be centralized.

Activities undertaken by the control reporting post and the air operations centre will normally be centralized into one facility, often in a single building. For small

countries with, say, six sensors giving coverage of up to 930 × 930 kilometres, this is a suitable air defence system architecture.

Control options

Command and control structures can be kept relatively simple and the number of expert staff required can be limited. The track database – targets that can be effectively monitored – would typically contain up to 300 tracks and controllers could handle up to len "close" and 20 "loose" interventions.

terceptions. Second, where air space management demands a significant number of sensors (more than six) and the defence assets such as guns and aircraft are distributed over large areas, a system with centralized command but decentralized control can

Groups of two or three reporting posts pass data to tactical command reporting posts which are normally termed sector operations centres when more than one sensor is connected. These in turn transmit their information to the air operations centre. This is the most defence system. The dispersed sensors and mobile command reporting posts concept is resilient to damage and the command organization is relatively easy to implement. Typically, each sector operations centre - the decentralized control - can handle 200 tracks and 30 control interceptors while the air operations centre - the centralized command - would have a track capacity of over 500 after combining all the inputs from the sectors. The third method is to distribute command and control responsibility to centres that exercise total authority in specified areas. Each then reports to

a centralized strategic

command function. This air defence architecture monte the annual when several states are involved or when a large centines tal area has to be defended It is an extremely complex task to define the hierarchy of command to identify and allow for overlaps of data, and to distribute this information ground the regions. It requires close co-operation between participating states

International integration

As well as accommodating the many variants of command and control, an air delence system design must allow for future expansion, not only within the country but also for integration with international air defence facilities.

The data processing

system is the key to this

versatility A well-designed

system will have modules of hardware and software that can be integrated in various forms depending on the requirements. It must at the same time be tolerant to failure and able to accommodate different computer types and software languages that are likely to be introduced as the system expands and equipment becomes obsolescent. The ideal architecture consists of distributed nodes of processing that are expandable in power. These are coupled via local area network (LAN) open system interconnection (OSI) standard data communications. Computers with applications software can be added to the local area network with no major impact on the logic system Availability can also be ensured by building-in spare computers coupled with automatic fault detection and techniques that ensure graceful degrada-

The hardware must be capable of installation in mobile cabins that can be transported by land, sea, or air, as well as in static facilities. Software, likewise, must be capable of being maintained and amended on sile to handle local environmen-

Compatible techniques

Most countries have many sensors rarely from the same supplier. The other command and control systems with which the gir defence network must interface are also likely to he different It is therefore unlikely that the data to be exchanged are of similar format The air defence system must use techniques that ensure compatibility at all levels from the reporting post up to the air operations centre while minimizing any impact on the central air defence data handling systems and the other systems with which it is interfaced. The distributed logic system architecture can readily accommodate the special normalizing processors needed to overcome these problems and they can be interfaced to the local area network by the appropriate open system interconnection

communications.

(LPS)

* John Nicholls is an Engineering Executive with Plessey Radar Systems • Oakcroft Road • Chessington • Surrey K19 102.

Voltage comparison on a 'scope

There is frequently a need, when experimenting with circuits, to measure or compare several DC voltages at test points etc. Since most readers are unlikely to possess more than one multimeter this can be rather tedious. Using this simple circuit, up to four voltages can be compared or measured on any oscilloscope that has a DC input and an external trigger socket. The circuit uses only three ICs, five resistors and a

canacitor The complete circuit of the voltage comparator is given in figure 1. The four voltages to be measured are fed to the four inputs of a quad analogue switch IC, the outputs of which are linked and fed to the Y input of the 'scope N1 to N3 and associated components form an astable multivibrator, which clocks counter IC3. This is a decade counter connected as a 0 to 3 counter by feedback from output 4 to the reset input. Outputs 0 to 3 of the counter go high in turn, thus 'closing' each of the analogue switches in turn and feeding the input voltages to the 'scope in sequence.

Output 0 of the counter feeds a trigger pulse to the 'scope once every four clock pulses, so that for every cycle of the counter the 'scope trace makes one sween of the screen. A positive-going This simple circuit allows up to four DC voltages to be measured or compared by displaying them side by side on an oscilloscope.

(H. Spenn)

trigger pulse is available via R4, or a negative-going trigger pulse is available from the output of N4 via R5. The resulting display is shown in figure 2, four different input voltages being fed to the inputs in this case. The oscilloscope timebase speed should be adjusted so that the display of the four voltage levels just occupies the whole screen

The supply voltage +U_b may be from 3 to 15 V, but it must be noted that the input voltage should be positive with respect to the 0 V rail and not greater than +U_b. If voltages greater than this are to be measured then potential dividers must be used on the four inputs.

Setting un

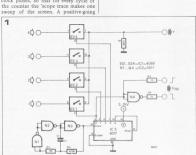
To calibrate the circuit, simply feed a known voltage into one input and adjust the Y sensitivity of the 'scope to give a convenient deflection (for example one graticule division per volt input). The unknown voltages may then be fed in and compared against each other and against the calibration.

The circuit can easily be extended to eight inputs by adding an extra 4066 IC and connecting IC3 as a 0 to 7 counter (reset connected to output 8, pin 9).



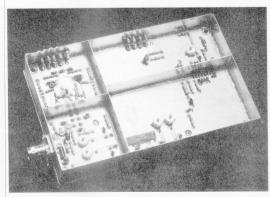
Figure 1. The circuit diagram of the voltage comparator.

Figure 2. An example of 4 random voltage levels displayed simultaneously on the scope.



INDOOR UNIT FOR SATELLITE TV RECEPTION-1

by J & R v Terborgh

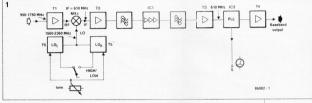


Following last month's general introduction to satellite TV reception, this article describes the construction and operation of the indoor unit (IDU). This is in essence an interface between the low-noise converter (LNB) at the dish aerial and a conventional television receiver. The first part of the article deals with the RF board contained in the IDU.

Indoor converter for satellite TV

- · Single conversion, wideband FM tuner
- Complies with standard LNB IF range (950...1750 MHz) and downlead food existing for CS and future DB extelline (1).
- selector, audio and video outputs, and switchable AFC.*
- Remodulator test and satellite scan circuits simplify initial setting up and dish positioning.*
 Also usable as a 23 cm band (1240...1280 MHz) amateur television

Before embarking on this project, and a la make absolutely certain that a la mand a Bar dish aerial can be securely installed to give an unobstructed line-of-sight path to the relevant scellinted, has stated last morth, it appears that garden installations are all right, but not installations are many and expert courself in this material results of the relevant planning permission. Careful planning permission careful planning permission careful planning permission careful planning permission. Careful planning permission careful planning permission careful planning permission. The planning planning permission careful planning permission ca



virtually impossible for most home constructors to build either the dish aerial or the low-noise converter, and these will, therefore, have to be bought or rented. In this context, see Satellite TV reception (p. 40) and Hartison Electronics' advertisement [0.85] in the Spettmber 1966 issue of Electronics Fortunately, the Content of th

Although the construction of the indoor unit is not recommended to absolute beginners in electronics it should be noted that a number of prototypes were built by constructors with only limited experience. In the main the results were fully satisfactory although all agreed that their task had taxed them to the full requiring not only great precision and care in soldering, but above all close attention to the constructional details. The present article therefore, aims at giving the maximum clarity to all matters concerning veryhigh-frequency techniques.

For an explanation of parameters and abbreviations used in this article see Satellite TV reception in the September issue of Elektor Electronics.

Block diagram

The block diagram in Fig. 1 shows that the indoor unit is a single-conversion superfeterodyne tuner. A low-noise amplifier raises the level of the 950-1750 MHz input from the LNB, which is then mixed with the 1560-2360 MHz output of local oscillators T and Ts.'

It should be noted that LNPs used for the reception of communication satellite TV programmes use a 10 GHz local oscillator to give an output of 1058-11.75 GHz. Fortunately, the European Broadcasting Union (EBU) has recommended (Literature reference [II) that LNPs for direct broadcasting satellite (DRS) services also

have an output of 950-1750 MHz.

coupled by band-pass filters, provide a gain of about 42 dB at the half-power bandwidth (>36 MHz). A phase-locked loop (PLL) demodulates the 610 MHz 1F signal an passes the baseband (about 0-85 MHz) to the video processing circuits (described in next month's issue) via buffer T₄.

The relatively high IF of 610 MHz ensures good rejection of the 2170-2970 MHz image frequencies, fi. (f=fio+fir)

Circuit description

In the circuit diagram of Fig. 2, the SHF input stage, T₄ a Type BPG68 transistor, has been designed for low-noise (Fas-4.5 dB max) wide-band operation. It presents a 50-ohm impedance to both the input from the LMB and to mixer MX. Its gain ranges from about 12 dB at 950 MHz to around 8 dB at 1750 MHz

MX: is a Type IPFBI monolithic, wideband, double-balanced mixer (DBM) consisting of bur Schottly diodes, which have a low junction capacitance and provide linear operation over a wide range of LO and RF power levels. These diodes are fed wa high-reliantly transformers to give a meniculously balanced set-up suitable for operation at high RF LO. suitable for operation at high RF LO. particularly transformers to fire internal or particular of the device is shown in Fig. 3a.

The Type HPFSII was chosen because of its robustness, excellent performance-to-price ratio, and stable impedance at all three pors, which are designed to handle a wide range of RF input signal levels. Bit drawbacks are its cost as compared with a discretely bull mixer, and its conversion loss. However, an active mixer, which would have some conversion gain, is difficult to keep stable over the RF input range of 950-1750 MHz. Moreover, the passive DBM virtually cause the carrier-tonoise ratio to be less impaired in the

The characteristic curves in Fig. 4 show some of the parameters of HPFSII. In particular, Fig. 4c shows the excellent performance of the device at a local oscillator power level of +7 dBm (about 5 mW). Since the input impedance, Z., at pin 8 is 50 ohms, the output voltage, Dio, of the local oscillator is given by $\frac{1}{2} \frac{1}{2} \frac{$

Readers interested in balanced RF mixers should find the RF/IF Signal Processing Handbook, Volume 1 (Literature reference [2]) well worth

Local oscillators Ts and Ts' cover the 1560-2360 MHz band at sufficient power for satisfactory operation of the mixer and have the stability required for widehand FM TV recention. Since it proved virtually impossible to achieve this performance with a single transistor, two varactor-tuned Type BFW92 transistors are used. The two sections of the oscillator, LOL, and LOH, are tuned to the highest and lowest channels of satellite TV services respectively by Cx and Cx'. Section LOL covers a range of about 1500-2000 MHz, and LOH operates over roughly 1800-2400 MHz. The stability of the oscillators is so good that automatic frequency control (AFC) is not, strictly speaking, required

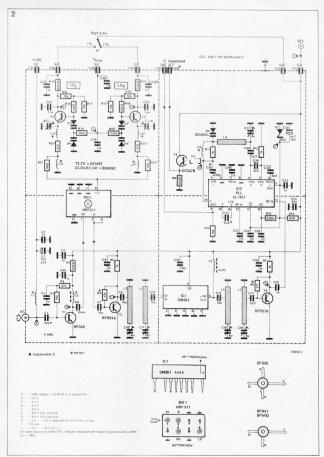
The relevant oscillator section is selected with St. Resistors Reo and Rev in LOu and Rev and Rev in LOu are damping resistors, which provide enough inductance to ensure correct matching to the 50-ohm LO input of mixer MX.

The common 3-32 V tuning voltage, V_{tune}, is applied to varactors D₃-D₄ (LOL) and D₃-D₄ (LOH) via resistors R₁₉ and R₁₉ respectively.

R₁₉ and R₁₉' respectively. The oscillator stages operate in the common collector mode: oscillation is achieved through positive feedback via the base-emitter capaci-

tance of the transistors.

Fig. 1. Block schematic diagram of the RF board in the IDU. Note that two local oscillators, LOL and LOU, have been incorporated to supply the 1560-2560 MHz injection stems.



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The 610 MHz IF signal is taken from 1 nin 2 of MV, and ganagitisely fed to a conventional amplifier To which provides about 10 dB gain at a relatively low noise figure: it also onsures correct termination of the IF output of MY.

The first IF band-pass filter consists of two critically to clightly overcritically coupled tuned line inductors In and La. Correctly aligned. these have a 3 dB pass band of about 40 MHz a relatively low insertion lose and cause minimal stray radiation Both the collector of To and the input of IC1 are canacitively coupled to a low-impedance matching tap on the relevant inductor

Second IF amplifier IC, is a widehand hubrid IC Type OM261 which is primarily designed for VHF/IIHF masthead aerial amplifiers and MATV customs This single-in-line (SIL) device contains a 3-stage RF amplifier as shown in Fig 3b. The OM361 was chosen for its high gain (about 28 dR at 600 MHz) and page of input/output matching Power to the final two cascaded transistors is supplied via choke Is to prevent the RF signal from being short-circuited by the thoroughly decoupled positive ennaly rail

Band-pass filter Le-Le and amplifier Ta have functions and characteristics similar to those of Lasla and To respectively. The IF signal at the collector of T1 is capacitively fed to phase-locked loop (PLL) decoder IC.

It must be stressed that the overall performance of the IDII depends to a large extent on the bandwidth. rather than the gain, of the IF chain, Since the deviation of the satellite TV signal is typically +13.5 MHzpp, and the baseband occupies some 8 MHz. the IF bandwidth must be not less than 35 MHz for satisfactory performance

It is, therefore, clear that the IF bandpass filters are crucial to the correct operation of the IDU. Since the combined gain of the IF amplifiers amounts to 48 dB and that of the IF chain is about 42 dB it follows that the total insertion loss of the filters is around 6 dR

Next month's article will contain measurement data relevant to the RF sections of the IDII PLL decoder IC2 is a purpose-de-

signed satellite TV FM demodulator active components intended for satellite reception systems (Literature

The functional diagram of the device is shown in Fig. 3c; inset is the onchip voltage-controlled (Clapp) osThe Clarm oscillator generates the 610 Mbs cub carrier for demodu lating the IF signal. It is tuned externally by line inductor Ls. varactor Do and trimmer Cas and coupled to one of the (differential) inputs (pin 6) of the phase detector via Co. The other input of the detector, pin 7, is decounled by Car The output newer of the oscillator is stated to be -10 dBm which is claimed to be the ontimum figure for threshold nevfermence (Literature reference (41)

Varactor D₂ provides a frequency-tovoltage gradient of about 14 MHz ner volt: at the most commonly used deviation of 13.5 MHzon therefore the hasehand output owing is about I Vpp (note, however, that some transponders are run at higher deviation unluoch

The RF amplifier in the PLL chin is a differential type with one input (nin 0 dRm

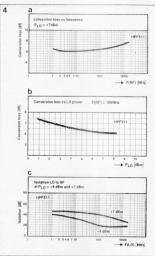
also serves as an PF block reactance Both outpute pine 15 and 14 ranget. ively are fed back to the relevant innut nins 16 and 1 respectively by means of canacitors which define the secondary loop filter response: the values of C20 and C21 may be altored to guit the domintion of the recoived signal: this will be reverted to in a forthcoming continuation of this article. The stated values of these components engure a PLL noise throughold of about 10 dB C/N at doug ations of 13.5 MHznn to 20 MHznn Careful redimensioning of the secandary loop arrangement may lower the PLL threshold to 8.5 dB C/N: this is not at all easy however and the matter will be taken up for evamination in due course Around the threshold level the PLL produces snarklies or snikes on the picture screen This effect however dissanthreshold

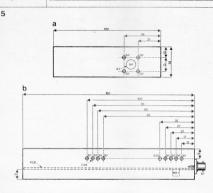
12) decoupled, which results in an inpears as soon as the C/N figure put handling range of -25 dBm to rises some 2.5 dB above the PLL Both video and inverted video are The automatic gain control (AGC) output the former is fed to Do via output of the SLI451 is used to drive primary feedback loop Le-Ru, which a relative signal-strength (S-) meter a 0 4 4 2 CMD 86082 - 3b - 012 Von - C2 VEE VEEZ

SL1451

Fig. 4. Graphs correlating a mumber of important technical character isstes of double-balanced mixer MX1. Remember that RF = 950...1750 MHz, IF = 610 MHz and LO = 400 MHz.

Fig. 5. Before fitting any parts onto the board, it is necessary to finish all drilling and filing of the metal enclosure sized 100 x 160 x 30 mm (W×L×H) nncl. of top and bottom lids. Fig. 5d shows the home-made version of feed-through Cut





circuit via nin 9

circuit via pin 9. Buller 7 is a simple emitter follower that servers to cutput the baseband at low impedance. Note that its output to be baseband at low impedance. Note that its output potent is required for use in the AFC and videe processing circuits. It is important that feedfirmough capacitor Gw. has a capacitance of not more than about 30 pF to prevent it filtering or limiting the baseband. The supply voltage to the PLL chips is sabilized at 82 LV by need ridote D, and it is also decoupled at several portions to prevent occiliator insability.

The dashed lines in Fig. 2 denote metal screens on the printed-circuit board: these provide effective protection against stray inductive coupling of tuned circuits and parasitic oscillations.

Finally, all DC connections to the RF board are decoupled by 1 nF feedthrough capacitors.

Construction

Contrary to the normal order in which electronic projects are put together, it is necessary to finish all mechanical work as detailed below, before fitting any parts onto readymade PCB Type 86082-1.

First, prepare a 160 x100 x28 mm (inside) brass or in sheet enclosure as shown in Fig. 5. If you can not obtain a preformed enclosure, you will need to cut four suitably sized pieces of 1. 2 mm thick brass, 12 mm the two of these as shown in Fig. 5a and 5b, and join them to form a net you using Sellotape at the corners to using Sellotape at the corners to maintain right angles as you solder, using a heavy-duty (2:100 W) iron. Brazing is, naturally, even better.

Shazing is, haurany, even petter.

Check whether the eight feedthrough capacitors and BNC flange
socket K₁ fit snugly into the holes; if
not, carefully ream the holes until
they do. Do not solder anything as
vet.

File a notch into the PCB to allow for the PTFE ring round the centre pin of K. Check whether the PCB needs any filing off the sides before it can be received into the box. Fix 6 by its four small screws, but do not secure these as yet. Pre-tin the holes provided for the

feedthroughs, and insert these from the outer side of the enclosure. Point them downward as you apply heat and solder; if all goes well, the capacitors should slide snugly into place while hot solder runs smoothly round the conical metal bodies. While soldering, carefully manoeuvre the capacitor into its final position.

Since low capacitance (10...27 pF) feedthrough capacitors are difficult to abtain items it may be necessary to make a DIY version from a number of parts intended for the isolating of nower semiconductors on heatsinks Fig. 6d chowe how a small washer hugh two coldoring tage and a holt nlus nut can be nut together to act as a low-canacitance feedthough It is definitely less alegant than a real canacitor but it works satisfactorily and has canacitance of about 50 pF. The PCR for this part of the project is a pre-tinned double-sided type equipped with 5 mm holes for Ti to To incl. and slots for Cas and Cas' Through-plating is effected by soldering component leads at both DCR eidae where required

Start off by applying some solder onto all ground holes on the PCB, as well as onto its edges at both sides: this will facilitate soldering at a later stage, and prevents overheating of grounded components when these are fitted Make sure however that holes remain open (use solder wick). Resistors: with a few exceptions in the LO sections of the circuit, these should have their leads neatly bent equidistant from the body with snipe-nose pliers. Pre-tin any resistor load that is to be inserted into a ground hole All resistors should be or 1/4 watt (except R14 which is 1/4 W) carbon film types: not metal film. Resistors should be fitted to rest securely on the PCB component side

Capacitons: In the case of a supply decoupling capacitor (Inf. 10 Apacitor) (Inf. 10 Apac

When societing the growth terminal at the PGB component side, solder can be observed to creep right up to the ceramic body, and spread smoothly ower the ground plane. Coupling capacitors do not require this method of pre-timing, although they should be mounted with the shortest possible lead length as well. Trimmers are to be pushed security to the relevant holes and soldered to the contract of the coupling that the soldered the contract of the contract of the coupling that the contract of the coupling that the contract of the coupling that the c

rapidly to prevent deforming of the

foil material.

Transistors with the exception of the BFW98s and the BC8478. b and c leads should be cut off to about 2 mm, e leads to 34 mm. Before fitting, note the terminal assignment of the BFG655 to get its position correct. Transistors: Transi Tran

5 c

the component side. The e leads should be soldered flush with the EPS side ground plane.

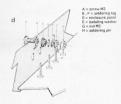
Inductors should present few problems, as their construction data and practical outlook are given in Table I and Fig. 7 respectively. Note that only two types of wire are required to make all inductors, except Ls. which is a commercial choke. The silver-plated tuned lines should be accurately bent and, with the exception of the longer Ls, pre-tinned at one end.

With reference to the component overlay and track pattern shown in Fig. 6, and observing the foregoing directions, the fitting of parts onto

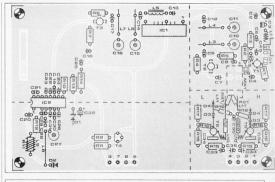
the PCB may now commence.

RF amplifier T₁ and mixer (see also

Fit all passive parts as set out above. Pay special attention to LNB block inductor L₁, which is fitted slightly off the board surface, and has one end soldered direct onto the RF input plane. Fit Ts in its pre-drilled hole, soldering the b and c leads direct onto the relevant tracks, the elastic firmly to ground. Solder SMD capacitors Cs and Cs with a light-duty (IS W) iron to prevent clamaging these devices. Alternatively, Cs and Cs may be 6p8 ceramic types mounted onto the relevant planes with the absolute minimum of lead enough (S) Sim ML and R must be



Inductor	turns	SWG wire	internal diameter	remark(s)
Lı	12	24 enam.	3 mm	closewound.
Lz	1	24 enam.	_	through 3 mm ferrite bead.
La;L4 La;L7	-	20 silv.		tuned line; length and location of tap governed by relevant PCB holes; fit 3 mm above ground.
Ls	-	20 silv.	-	as above but no tap.
Lo	5	24 enam.	Rii	closewound on R11.
L10; L10'	1%	resistor lead	3 mm	spacing 1% mm initially; see Fig. 8c.
Lii(Lii'	-	resistor lead	-	tuned line; see Fig. 8c.



Parts lies T. - DEGSE (Mullard) Miccellangous (All miniature ceramic transznidal (leadless T-: T- RER91(A) MY - HPES11 or ceramic chin) (Mulland: Motorola) learl spacing 2.5 mm SRA11 (Mini Circuite) unlace otherwise stated) T. - BC547B S: = miniature SPDT (use 7.5 mm carbon film C+:C+=10 n SMD* T. T.' - BEIAID? K1 = square flange BNC types feedthrough capacitos (Mullard: Motorola) Br:Ba:Bas:Bas:Bas:Bas:Bas socket & 4 off screws 3 mm diameter Bus' - 10 k RE-tight metal enclosure Ces = 10. 47 p B> = 82 k with detachable lide: feedthrough capacitor Rs-470 O 100 v 160 v 30 mm Industore 3 mm diameter* R4 = 33 k Ca = 10 u-25 V tantalum Ls = 2µH2 axial choke W×I×H B. B. D. D. - 1 b PCB type 86082-1 (see Remaining inductors are Re - 27 k Readers Services) home made using p. _ sen o nither O.E. B. - 330 F Cm = 10 n D. - 8V2 zenerdinde (SWG24) enamelled Ru = 47 O. K. W. 400 m\A copper wire or 1 mm Ris:Ris' = 220 ♀ (SWG20) silver plated R18;R18' = 68 Ω C21 = 6p8* D4' = BB405G wire. Refer to Table 1 R19: R19' = 100 k IC1 = OM361 (Mullard) Ferrite head (3 mm) for Rzo:Rzo':Rz1:Rz1' = 10 Q C32 = 4µ7:16 V tantalum IC2 = SL1451 (Plessey)

Fig. 7. Neatly

capacitors Cu

+ LNB block coil

IF amplifier Solder the MX1 connection of C7 at both PCB sides, but that to the base of T2 at the EPS side only.

transistor body (b and c terminals re-

spectively); note that R1 may have to

he mounted slightly asymmetrically

to ensure minimal stray inductance

MX: is located at the EPS side of the

PCR, while its eight pins are

soldered at the component side.

Note that the RF input (pin 1) is

marked in blue for location pur-

at the transistor base

noses

Tuned lines Lo, La, La and Lo are best fitted as follows (see also Fig. 8b). Insert a left over component wire into the PCB holes provided for the taps. and solder at the EPS side. Use the protruding pin at the far end of the vernier gauge handle to determine a wire length of 3 mm above the com-

ponent side ground plane; cut the soldered as close as possible to the wire and level its top with a few strokes of a small file, while the wire is held securely in pliers. Pre-tin the top and position the wire at right angles to the PCB Mount the silvered line, pushing it into place until it rests on the tap wire end. Make sure that the inductor is precisely angled and that its horizontal part is always exactly 3 mm above ground. Solder the trimmer and double ground connections, and then the tap. Remember that any excess solder on its silver plated surface may degrade the inductor's O-factor. Make sure that the coupled lines run parallel and at identical height above

> After inserting the pins of the OM361 until all studs rest on the PCB surface, they must be soldered rapidly (five pins twice to ground), after which the SIL chip must be bent

ground.

downward with its twoe indication facing the PCB component side ground plane. Do not use too much force or one or more of the pins may come break off

Fitting the remainder of the IF amplifier components should not cause difficulty, as the suggested methods for mounting have already been de-

tailed above

PLL and baseband output.

Mount IC2 without an IC socket, and remember to solder pins 2 and 8 at both PCB sides. The surrounding capacitors and resistors should be fitted as set out, while block inductor R11-Le must be mounted at a small distance above the board (1 mm) to prevent any likelihood of a shortcircuit. Tuned line Ls is fitted at precisely 3 mm above ground. Mount varactor D2 with the minimum of lead length at either side of its glass body. Make sure that it is really a BB405G: ring, the latter indicating the cathode

Local oscillators (see also Figs. 8c

You are now well on the way towards completing the RF board, but the toughest part is yet to come: no PCB holes in many cases and a few narts mounted three-dimensionally and not it is not as difficult as it may seem

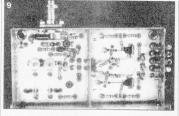
Note that all part references in the following description also apply to the corresponding accented (1) parts unless a specific description is thought necessary to make a distinc-

Fit decoupling and hias parts Ris. R16, R17, C13, C25 and C16 as set out above. Pay due attention to the fitting of Te as it has neither a hole nor any tracks to connect to other components. As illustrated in Fig. 8a. the transistor's collector lead is to be sharply bent where it leaves the enclosure Push-fit the lead into the slot along with chip capacitor C34, until the latter's shoulders rest firmly on the PCB surface. Gently manoeuvre the decoupling capacitor and tap the transistor until this is felt to lie level onto the PCB surface. Note that emitter leads of To and To'



should face one another requiring To unlike To' to lie with its type indication facing the PCB ground plane. Carefully solder the track and double ground connections of the chip capacitor and make sure that colder greens un along the metallized area and the collector lead. whose excess length is then cut off. Shorten the transistor's e and b leads to 2 mm and pre-tin them. Fit stopper registor Ris with the shortest possible lead length (≤1 mm) as close as possible to the transistor body (b): this may require the other lead (to junction R16-R17) to be rather longer than usual, but this is of no consequence Sharply hend the anode load of varactor De pre-tin and solder to ground (2x) using the hole provided Note that the ground connection of D4'. (LOH) is closer to Ts' than that of Da to Ts (LOL), Shorten the D4 cathode lead to 2 mm. pre-tin, and do the same with D3. Carefully join these parts and run the appropriate length of the D1 anode wire to junction RisTs. Since junction R19-D1-D4 should exhibit the absolute minimum of stray capacitance

8 types only. of 1mm Cu An



and inductance Rio needs to be prepared as follows. At one side of the resistor body, the protective lacquer should be scratched off where the wire leaves the body. This is conveniently done by holding the relevant area in pliers and twisting the resistor until the brittle ctuff comes off. Shorten the lead to 0.5 mm, pre-tin, and join it to junction Da-Da with a minimum of solder. Note that the other lead of R19' (and of R10) must be left much longer so that it can reach junction Ris-Ris-Cas. Since these resistors act as current limiters and chokes to the SHF signal on the varactors, this length is of little importance

Inductors Lie and Lii are made from the terminal leads of Rzo. One lead is wound as 11/2 turns on a 3 mm former. which may be nail, screwdriver shaft. or even a ball-point refill, as long as it has a diameter of 3 mm. Leaving the turns to revolve around the former, the resistor is gently pulled back until the lead length between resistor body and start of winding matches that given in Figs. 7 and 8c. Space the turns as shown The other resistor lead is to act as L11.

Observe its length, and edge the remainder of the wire two times as shown in the illustrations. Put the prepared resistor & inductors aside for the moment, and proceed with the most exotic, yet simplest, part of the board: Cx, which is simply some 10 mm of left-over component wire. 2 mm of which is slightly bent, soldered to the To e lead, and pointed towards C36. The wire should not touch ground, of course. Solder Lio to junction CxTs(e); this requires some skill to prevent shortcircuiting the inductor turns by either Cx or the Ts emitter lead Check for any short-circuits caused by excess solder, and carefully bend Cx to point to the body of C16 The oscillators will not operate correctly if Cx is left out Run R20-L11 exactly parallel to D3-D4

and solder Lu to ground straight onto the PCR surface. Note that no ground hole has been provided: use the relevant illustrations and the component overlay to find the correct location, level with MX, nine 7 and 8. Ras should now be positioned well above all other components. Solder R21 very close to R20 and run the other end direct to mixer pin 8. As Rai' should have exactly the same total length as its LOs counterpart. the Lid-Ray-Lid line needs to be mounted slightly slanting with respect to the Da'Da' line Ground Las at the appropriate location and check the outlook of the LO sections against Figs &c and 9 PCR

Recheck all soldering joints at both sides of the PCB, and remove any stray bits of wire or solder. With a sharp appliance and a cotton bud dipped in 95% alcohol remove all excess solder flux, visible as brownish matter, from etched surfaces in the RF input and mixer stage; do the same at the PLL section. If you have so far followed the instructions, terminal holes 1-8 incl. should still be open. Enclosure

Fix K₁ securely by its four screws whose heads should be at the inside of the enclosure. File off any protruding thread until it is flush with the socket flange.

Insert the completed board into the enclosure making sure that the centre pin of the BNC socket rests on the RF input plane (Li-Ci): file or cut off any excess pin length. Refer to Fig. 5b for the positioning of the board and make sure that the bottom lid can be pressed or screwed on without touching MX1. Use a heavy-duty iron (>50 W) to

solder the PCB into the enclosure; depending on the type of metal sheet, some pre-heating may be called for to be able to solder at all. Use an additional soldering iron or place the enclosure on the hot surface of a thermostatically-controlled smoothing iron: you will find that once the metal surfaces are reason ably warm to the touch coldering hecomes much easier

Mount eight soldering pins in the terminal holes if the urine of the food through capacitors are not long enough

Hsing the dotted lines on the PCB overlay as a guide, solder three 17 mm high metal screens onto the PCB component side (take care not to damage nearby parts). Note that the longest screen is to run right over IC. on that a 20 v 4 mm recess halo should be made at the correct location

If you have made your own metal enclosure do not forget the top and bottom lids which are to be screwed on after the box has been fitted with at least eight square brass nuts soldered into the upper corners. A few additional nuts and screws along the enclosure side panels are of course, good practice to make for an RF-tight unit. Finally, drill the top lid. as shown in Fig. Sc.

Next time

Part two of the article in next month's issue will describe details of the vision and sound processing circuits, the power supply, and the Smeter driver. Also, the alignment of the IDU will be gone into, and measurement data relating to its performance will be presented and discusend

Literature references:

[1] Document D46: Choice of the first IF frequency range for DBS receivers. EBU Technical statement ref. EBII D46-1985 (F)

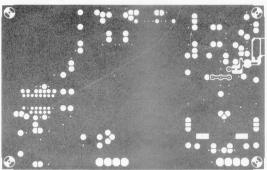
121 RF/IF signal processing handbook, volume 1. Mini Circuits New York.

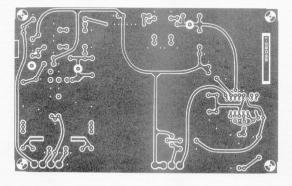
[3] Satellite Cable and TV integrated circit handbook. Plessey Semiconductors.

[4] Application note 56/SI/00013 (SL1415). Plessey Semiconductors.

Important notice

Information on component availability for this project will be given in Part 2, to be published in next month's issue. Meanwhile, many parts are available from Bonex Limited: 102 Churchfield Road: Acton: London W3 6DH: telephone 01-992 7748: Universal Semiconductor Devices: 17 Granville Court-Granville Road; Hornsey; London N4 4EP; telephone 01-438 9420; or Cirkit; Park Lane: Broxbourne: Herts EN10 7NQ; telephone: (0992) 444111.





JOCKEYING FOR SUPREMACY IN EUROPE'S OWN SPACE RACE

hy Tim Furnice

Within the next ten years the Furnnean Space Agency (FSA) will be operating an autonomous space station known as Columbus It will comprise manned medules and laboratories free-flying platforms and other equipment launched by the United States' Space Shuttle and the proposed European Ariane 5 rocket It will be serviced by the plane Hermes and possibly by the British up. As a member of ESA, the United Kinadom will play an important role in these projects not only with Hotol, but also particularly the free-flying platforms for Earth observation astronomy and materials processing. Britain's financial contribution to ESA is 12.9 per cent and its participation in mandatory ESA programmes represents 16 per cent of the effort and

mannower There is a thriving space industry in the United Kingdom and this has been involved in the building and operation of over 50 satellites 2000 sounding rockets and over 100 ground stations. Unlike that of many European countries British influence in space technology and commerce spreads beyond the continent itself, and especially to the United States of

In The Satistics of the Manager of t



The European Communications Satellite 2

More versatile

These include GFC-Marconi (2) for communiothers involved are Ferran-Centronic, Thorn-EMI. Racal. Software Systems. BAJ Vickers and IMI Summerfield. These manufacmicrowave tubes detectors solid state devices digital data recorders software, gyro packages, and racket maters RAe pioneered the use of three-axis controlled communications satellites. which are more versatile and can be built on a much larger scale for the multitude of developing applications, such as direct broadcast telemaritime communications. and business services. The company has developed a stable of complatforms: the European Communications Satellite (ECS), Eurostar, and Olympus. The ECS 2-Eutelsat series satellites being built by BAe have 12000 voice circuits, two television

channels and two reneaters to handle business traffic. They have a 1 kW capacity Three military communications satellites known as Skynet are being built too. These are also based on the ECS "bus" and include a communications payload from GEC-Marconi comprising four super high frequency channels. two ultra high frequency channels for voice data and telex and one extra high frequency experimental uplink Power generation is 1.25 kW

Aircraft phone calls

Three Eurostar satellilles are being bull for the London-based inter-notional marilime organization, Immarsat, on a contract worth \$100 million. Producing 0.75 kW of power, the Immarsat 2 satelliles provide independent L band ship-to-share and C band shore-to-ship communications, with 250 commun

provide aircraft communi-

cations enabling passengers to take and make telephone calls on civil aircraft.

The Furnstar satellites can generate as much as 2.3 kW of power but this is weak compared with the world's largest communications satellite Olympus one model of which can generate 8 kW enough to power 42 direct broadcast television channels The next British Aerospace satellite under development is called the Ria Communicator The concept envisages clusters of nowerful communication satellites (comsats) sharing aeostationary orbit, providing television broadcast and fixed and mobile communications services Inter-satellite laser links will allow communications within and between clusters via crateway satellites Bia Communicator are planned the largest being for direct broadcast television. This would generate 15 kW from a 50 m long solar array and carry 16 high power television channels BAe also has a contract to build equipment for Intelsat 6 the next generation of

Spectacular

satellites for the inter-

national telecommuni-

The company produced a significant Spacelob hard-ware which flew on Space Shuttle missions dedicated to Europe, the United States, and West Germany in particular in 1983 to 85. Twenty of the Spacelab pallets have been delivered to America's National Aeronaulies and Space Administration (NASA). These are used as

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the essential mounting points for equipment in the Shuttle payload bay The European spacecraft Giotto which had its rendezvous with Hallev's comet last March returning spectacular data, was built in Britain with BAe as the main contractor The \$45 million contract is just one of a number of key science and applications satellites operated or planned for Europe and to he built using British ev-

pertise.
These spacecraft include the Ulysses international solar polar spacecraft, the European Remote Sensing spacecraft (ERS 1), Exosat, international Ultraviolet Explorer (IUE), interned Astronomical Satellite (IRAS), and the Geostallanary Orbiting Satellite

(GEOS 2):
The solar panels that will generate electrical power for the giant Hubble space telescope, hopefully to be launched by Shuttle later this year, were manufactured by 8Ae as a huge foldable array. The company expects to build a set of replacement panels under a \$7 million contract.

contract.

Britain is investing \$58 million in joint science and industry programmes covering remote sensing, data acquisition, processing, dissemination, and forecast. The Royal Aircraft Stabilishment's National Remote Sensing Centre at Farnborough co-ordinates this activity.

In the meteorological field, SEC-Marcroni is

this activity.

In the meteorological field, GEC-Marcon is developing Europe's first advanced microwave sounding unit to fly on a United States' National Oceanographic Administration Agency (NOAA) satellite in 1990. Britain is a world leader in satellite instrumentation for remote sensing sageceraft.

Close relationships

The British National Space Centre (RNSC) formed in 1985 will in future coordingte the country's burgeoning space industry Rased in London with a small staff it will formulate a national space policy to be presented to the Covernment in June 86 To be effective it should cover the next 15 years The BNSC will need to establish close relationships with industry including the non-gerospace sector. both in contractual development and exploitation and commercial space operations It needs to provide a coherent voice on space matters seeking comprehensive rather than a fractional anproach and to consider its role in education and public policy The centre's directorgeneral is Dr Poy Gibson who, as the European Space Agency's own first director-general helped establish it and develop Europe's prestige in space. It is expected that Britain's space budget under his control will be doubled over the next two years to about \$300 million to reflect the increased importance the country places on space Although the United Kinadom only plays a small part in the Ariane launcher programme -Avica Bada Ferranti and Midland Bank's share represents just 2.4 per cent - BAe has proposed a revolutionary launcher to beat them all including the proposed Ariane 5. Hotol, an initially unmanned spaceplane, will be the world's first single stage-to-orbit (SSTO) satellite launcher and the first to take off and land like an airliner. It will cut by half the cost of deploying satellites into orbit. Indeed, the measure may be greater than that. BAe says it could place a five tonne payload into low

Farth orbit at a fifth the

cost of current vehicles.

Complementary or replacement

The revolutionary engine for Hotal is designed by Polls-Povce and will be dual-functioning It breather outside air like an ordinary airliner and mixes it with on-board supplies of liquid hydrogen during the initial climb through the atmosphere Hotal then switches to internal fuel supplies of liquid hydrogen and liquid oxygen, once the air at altitude gets too thin It is expected to cost \$520 000 million to develop and whether it goes ghead will depend on whether it is accepted by Europe as a complementary vehicle to Arigne 5 and Hermes or even as a replacement for Hermes which does not meet with universal anproval within Europe. So far only about \$5 million has been forthcoming for a proof-of-concept study and Dr Gibson hopes to be able to present the Hotol case to ESA before the end of this summer Although the French Harmas manned space plane has more short-term support Hotel is conceived as compatible with the United States' Space Station and its eventual European counterpart. It will also be manned for some sorties Ultimately visionary engineers see Hotal as the successor to Concorde carrying a passenger pod in its payload bay on a journey between Londen and Sydney, Australia, in 67 minutes

Enormous potential

Like France, the Netherlands, West Germany, and Italy, Britain has a squad of astronauts, or more correctly, Space Shuttle payload specialists. Two of these are due

to fly Shuttle later this year and early in 4087 primarthe te halp in the deploy ment of Skynet 4A and 4B military communications catallites They will begin British experiments into microgravity processing The notential of this business is anormous and the BNSC is anxious to educate British industry as to its possibilities Kodak Itd a subsidiary of Eastman Kodak in the United States has already flown experiments on the Shuttle and a fluid physicist from the company may be joining a crew in 1987 to 88 to onerate his own exneriments Clearly commercial operations are some way off. perhans 20 years away but vital research and development work needs to be done in space now. This is an area where Britain has been slow to move but it has the capability to catch up with France and West Germany, which are already forging ahead in

this field

(I PS)

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RF CIRCUIT DESIGN

* The first three appeared in the March, April, and May issues of Elektor India The fourth in this series on RF circuit design* describes a superregenerative short-wave receiver that can be coupled to a frequency counter for an accurate readout of the frequency of the received signal.

superregenerative short-wave receiver

A superregenerative receiver is provided with ample positive feedback so as to be capable of oscillation at the desired radio frequency. It is also provided with a means by which oscillations can be stopped or started at will. During normal operation, the relevant circuit is just oscillating.

Block diagram

From the blook diagram in Fig. 1 is seen that the RF signal intercept by the aerial is fed to an RF stage, which not only serves to amplify the signal but also to decouple the aerial from the remainder of the receiver. The amplified signal is fed to a buildr and a desector stage. The output of the buffer may be used to drive a frequency counter to give a read-out of the received frequency. The demodulated output from the detector is passed through a low-pass filter

Solitar Solitar Country Country Solitar 1

with a cut-off frequency of 5 kHz and then applied to an AF amplifier. The audio output is sufficient to drive a pair of headphones, but may also be used to drive a more powerful AF amplifier.

Circuit description

With reference to the circuit diagram in Fig. 2, the aerial signal is applied across potentiometer Pt, which enables the signal to be set to the correct level, as will be explained later.

MOSFET T₁ amplifies the input signal and decouples the aerial circuit. The amplified signal is applied to a detector, the G-S junction of T₂, via circuit L₂-C₁-C₂-C₃-C₃-C₃, which is tuned to the frequency of the incoming signal.

Part of the RF signal is applied to the G₂-D junction of T₂ from where it is fed back inductively to the tuned circuit. As this feedback is positive, oscillations tend to be set up in the tuned circuit at the frequency of the received signal. These oscillations

are quenched by the resistance of P_2 , depending on its setting, so that this potentiometer affords a means of bringing the tuned circuit just into

oscillation.

The demodulated output at the source of T₂ is applied to low-pass filter L₀-C₁-C₃-C₃, which has a cut off frequency of about 5 kHz. Since many short-wave stations operate at 5 kHz channel separation, the filter provides effective adiacent-channel

The audio signal is then amplified in T_4 and T_5 whose gain is sufficient to enable a pair of high-impedance headphones to be driven from the AF output across C_{12} - C_{15} . If the audio output is used to drive an additional AF amplifier, the value of C_{19} should be reduced to 1_{17} .

suppression

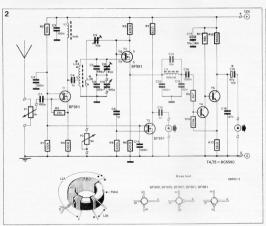
The signal at the drain of T_2 is also fed to buffer T_2 , whose output may be used to buffer T_3 , whose output may be used to drive an external frequency counter. This is a very useful means of obtaining a read-out of the frequency of the received signal, which makes operation of the receiver immeasurably easier.

Fig. 1. Block diagram of the short-wave receiver.

Table 1. Winding

Band	L2A (turns)	tap at (turns)	L2B (turns)
120 m	132	12	7.5
90 m	99	9	5.5
75 m	82.5	7.5	4.5
60 m	66	6	3.5
49 m	54	5	3
41 m	45	4.5	2.5
31 m	34	3.5	2.5
25 m	27	2.5	2
19 m	21	2	1.5
16 m	18	1.5	1.5
13 m	14	1.5	1
11 m	12	1	1

The core is a Type T50-6 RF toroid available from Cirkit (telephone 0992 444111) or Bonex (telephone 01-992 7748), while the winding wire is 0.3 mm dia enamelled copper.



Construction

The receiver is constructed on the Universal RF Board Type 8600, which is available through our Readers' Services. As it is an unpierced copper-clad board with fifty-seven isolated tracks, it is also available from most electronics relatiers. A suggested component layout is shown in Fig. 3.

Chokes L₁ and L₂ are commercially available components, but inductor L₂ must be wound as shown in Fig. 2. The number of turns for the

various short-wave bands are given in Table I. It is imperative for correct operation of the receiver that the coils are wound in the direction shown and that correct polarity is observed (this is facilitated by the large black dots in the circuit and on the coil drawing).

Operation

For optimum performance, the G₂-D section of T₂ should just oscillate. This is achieved by setting P₂ to roughly its centre of travel and ad-

justing C_{S} till oscillations just occur: this is indicated by a whistle in the

headphones or loudspeaker.
The input level is then set with Ps: if
this is too high, cross modulation
occurs, i.e. apart from the wanted
station, others are also audible. If the
aerial signal is too weak, the detector
does not operate correctly, and the

signal is hardly audible.

It may be necessary to adjust P₂ slightly before optimum performance is achieved: only when this is so, does the frequency counter indicate the frequency of the received.

Fig. 2. Circuit diagram of the short-wave re-

Parts list

Resistors: R₁;R₂ = 100 k

R₃ = 27 k R₄ = 100 Ω R₅;R₆ = 470 Ω R₇ = 82 Ω

R₈ = 220 Ω R₉ = 4k7 R₁₀ = 220 k R₁₁ = 56 k R₁₂ = 560 Ω R₁₂ = 68 Ω

potentiometer P₂ = 5 k linear potentiometer

$$\begin{split} &C_1 = 100 \text{ p} \\ &C_2; C_{11}; C_{12} = 100 \text{ n} \\ &\text{ceramic} \\ &C_3 = 10 \text{ n ceramic} \\ &C_4; C_{12} = 1 \text{ n ceramic} \end{split}$$

C₅ = 10 p trimmer C₆ = 1 p C₇ = 68 p NPO C₈ = 40 p trimmer C₉ = 82 p NPO

C₁₀ = 82 p NPO C₁₀ = 100 p variable capacitor

C14 = 10 n C15 = 22 n C16 = 330 n

16 = 330 n 17 = 10 μF;16 V 18 = 47 n

Semiconductors: T₁;T₂;T₃ = BF981 (= BF900 = BF905 = BF907 = BF961) T₄:T₅ = BC550C

Miscellaneous: L₁=1 mH L₂=see text and

Table 1 L₃ = 100 mH AF output socket RF output socket RF board 85000 Metal case of about 135 × 150 × 75 mm

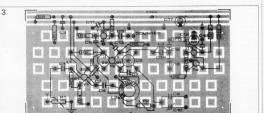


Fig. 3. Suggested component layout of the short-wave re-

HOW MIICH LONGER WILL SILICON RE HISED?

It sounds rather strange against the background of the present development of microelectronics to ask how much longer silicon will be used The first quantities of one-megabit dynamic memories using evisting silicon technology have been appounded recently while four-megabit dynamic memories are expected in 1988. These are the most outstanding current examples of the state of the art of silicon microelectronics These developments in largescale integration (LSI) have heen due to process technology or to put it the other way around it was mastery of process technology that made this progress in large-scale in-

tegration possible. A reduction in costs per bit on an integrated device went hand in hand with this large-scale integration

This is demonstrated by Fig. 1 which shows the evolution of costs per bit for the various generations of dynamic RAMs as "learning curves". The learning curves for onemegabit and four-megabit dynamic RAMs are estimated values. Before turning to the guestion of the limits of silicon technology and its replacement by gallium arsenide, we shall first briefly outline the development of silicon technology.

By the standards of microelectronics, silicon technology is a "very old" technology. It was 25 years ago, in 1961, that the first IC was developed by Kilby in germanium and one vear later in silicon. This process led in only 25 years from a small number of transistors on a chip to more than one million transistors in regular logic devices on the one hand and to more than a hundred

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thousand transistors on a chip in non-regular logic devices on the other hand In other words the complexity of the circuitry has increased by more than a hundred thousand times in this period of

After these developments is a competitor now appegring on the horizon in the form of gallium grenide? The worldwide market potential of gallium arsenide is estimated at 3.2 hillion dollars for 1992 a considerable amount when one considers that ea the Corman microelec tranias markat was worth about one billion dollars in 4085

Against this background one might after all be justified in asking how much longer silicon will he used in order to answer this question we shall consider the following points

· the mechanisms of substitution which result

in the replacement of a technique or technology by another:

- e the limits of silicon:
- a the limits of intogration techniques:
- the development of the market for silicon and adlium arrenide

Mechanisms of substitution

A technique or technology is only replaced by another under the following conditions

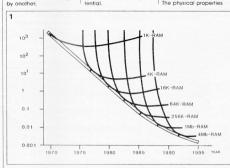
 Techno-economic limitations of a technique become apparent Le substitution results in cost eavings

- A faster evalution of an alternative technique is expected and at the same time a tendency towards areater efficiency In such a case a substi-
- tution is frequently made as a future investment As well as the actual
- replacement of the existing technique a new technique promises completely new applications A substitution is made with a view to innovative no-

limite of cilicon

In order to assess the limits of siliagn and possibilities of the alternative material gallium arsenide it is first necessary to consider the physical properties and also the technological status of the two materials A comparison of the physical properties of the two basic materials reveals three salient factors

- a the much greater electron mobility of Gale which means that can siderably factor aircuits
- can be realized with GaAs. . the much greater thermai stability of GaAs
- and areater resistance to radiation which would be of particular advantage with very fast and highly integrated memories: · a worse ratio of elec-
- tron mobility to defective electron mobility in the case of GaAs which also means that complementary electronics can be less easily used in GaAs than with silicon. The physical properties



only represent one side however le order to make a final judgement we also have to take into account the state of the art in the two technologies. This has been done for silicon and GaAs in Table 1 If we look at this table we see that the fault density for silicon chips is more than a thousand times less than for GaAs This is due to a considerably greater uniformity purity and surface smoothness in the case of silicon chins: in other words as a starting material silicon can be much better controlled than GaAs, which in turn results in far greater efficiency. We can also see that silicon chip surfaces are now more than 50 mm² in size compared with 40-45 mm² for GaAs in other words considerably larger and more complex ICs can at present be fabricated with silicon On the basis of this table. it can be said that GaAs is at present technologically about a hundred times behind silicon in complexity, or more than two generations of components behind. The same conclusion is reached if one considers the evolution of the complexity of integrated circuits as shown in Fig. 2. The thick line represents the evolution of the complexity of silicon circuits and the

Technological status 0: GaAr 2" 011 Chin diameter - 10 / cm² > 104 / cm² Couls donnier chin uniformity - chin nurity surface emonthmer 40 45 ---- 2 Chin audanes > 50 mm² 104 Components / IC 106

thin line the evalution of GaAs circuits We can see how silicon has evolved to the fourand 16-megabit dynamic PAM while GaAs has developed to the fourkilobit RAM. Fig. 2 does

Table 1

not show the production status of these circuits but the time at which the first design models were nrecantad If we look at the two

curves for silicon and

GaAs we have to con-

clude that, even if we assume a more rapid development for GaAs than for silicon, it will not attain the degree of complexity of silicon until 1995 Such a rapid development of GaAs is not to be expected and we should assume that the broken line with shorter strokes is more probable so that even in the year 1995 we can exnect a difference in complexity of more than ten

between silicon and GaAs If CaAs is not going to catch up with silicon in the next ten years as regards complexity what about the advantage of greater speed which components constructed on GaAs have?

An indication is provided by the evolution of the gate delays of integrated circuits based on silicon technology. As an example. Table 2 shows how gate delays in MOS processes in the Valvo plant (part of Philips CmbH in W.Germany) have developed from 1979/80 to 1986, together with the expectations for

1088 Along with the reduction in the smallest geometries and the associated reduction in gate delays we can also observe a simultaneous increase in the size of the chip surface and in the number of

components per chip and per mm2 This means therefore that not only the individual components on the chin have become faster but that the total ohin sizes and number of components have grown very rapidly. At present chips are produced which are 40-50 mm² in size while chips up to 100 mm² are being developed and will be produced in 1987. This implies that from 1988 chips between 50 and 100 mm² will represent the state of the art. At the same time the length of the circuit on such chips will also increase so that a length of 10 mm on a chip of approximately 80 mm² will not be exceptional If however we wish to determine the propagation delay on a circuit which is 10 mm in length and assume a value of 1010 cm/s for the signal propagation, we obtain propagation delays of 0.4 ns This means therefore, that with chips whose geometry is smaller than 1 um and with chip surtaces of 100 mm² the speed of the components and the propagation delay between the components are in the same order of magnitude. From the above observations, it can be deduced that with highly

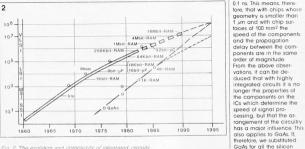


Fig. 2. The evolution and complexity of integrated circuits.

components on a highly integrated circuit of this kind we would scarcely after their speed, as this is largely determined by the propagation delays he tween the individual comnonente

Limits of integration techniques

These observations show that in highly integrated circuits the speed cannot he the decisive factor for a changeover from silicon to GaAs and hence for the replacement of silicon technology Hence an assessment of whether silicon is likely to be replaced can only be made if we first answer the question concerning the limits of silicon technology. We must first clarify therefore whether silicon is more likely to come up against technological limits than GaAs The question concerning the limits of silicon technology raises, however, questions concerning the general limits of integration techniques, which basically exist independently of whether one uses silicon or GaAs as the starting material. They do very much depend however, on the smallest geometries that can be used and on the process technology required for these

If, for example, we consider the vield loss in 64 K dynamic memories approximately 70 per cent is due to random defects, i.e. defects which are caused by the lithographical and deposition processes. About 10 per cent is correlated to the structure, in other words is due to geometrical tolerances. and only about 20 per cent is connected with device parameters, i.e. directly linked with the processing of the silicon. The physical limits for vertical and lateral structures are approximately 0.05 um for bipolar transistors and approximately 0.1 um for

MOS transistors. The limits are set by the minimum dimensions of the space charge regions of the pn junctions which at room temperatures and voltages of 4 V are approvi mately 0.03 um For the limits that can be reached in practice we can make the following estimates For lithography and etching techniques it is not possible in terms of production to go below structures of 0.1 um. Insulation requires geometrical distances of about 0.5 um. In order to keep the contact resistance at a tolerable level for components of less than 100 ohm, the contact holes should likewise have a diameter of more than 0.3 µm. For the pitch, by which is meant the line width plus the spacing between it and the next line. it will not be possible to ao below 1.0 um above all for reasons of reliability The limits that one can expect in practice are thus higher than the physical limits. It is not the physical properties of silicon which set the limits for integration techniques, but the processing limits in lithography, insulation. contact diameter and nitch How then is silicon tech-

nology expected to develop in the years 1990 to 10057

Table 3 gives an estimate of what is expected in 1990 to 1995 on the basis of present technological knowledge. For the year 1990 structures of 0.3 ..m are expected in the see and generation with chip surfaces between 100 and 200 mm² The difference between the first and the second generation can be seen in the lithographical process While light-optical processes and steppers are still used for the first generation, the second generation will be based on processes that use Xray lithography as structures of 0.3 um can no longer be realized with light optics. The limit for light-optical processes is put at about 0.5 to 0.6 um Relow this limit it will be necessary to use new processes such as X-ray lithography Developments in this direction are already taking place and it is to be expected that they will be available for production in 1990 These are projections for MOS devices It is also interesting however to take a look at the right-hand side of Table 3, which shows the expected development of bipolar deresults in limit frequencies for bipolar silicon components of 12 GHz and of 40 GHz in the second gen

This means that on the basis of bipolar silicon technology with devices of the first generation, it is possible to construct systems with transmission speeds of 2.4 Ghit/s and up to 10 Ghit/s with devices of the second generation. The degree of integration however will be considerably lower than with MOS circuits Sillcon elements will therefore, also be suitable for the construction of very rapid signal processing systems

If we now return to the question which was posed initially namely how much longer sillicon will be used and the related question of substitution we should consider the three 1 substitution in order to

- save costs 2. substitution as a future
- investment and 3. substitution for the purpose of innovation.

Point 1: costs per bit for silicon were reduced by more than a thousand times between 1970 and 1985.

Point 2: integration techniques, and not the properties of silicon devices will set the limits.

Table 2 Development of gate delays

Example: MOS processes Valvo valve and semiconductor plant

Year	1979/80	1982	1984	1986	1988
Process	1100	700	500	300	"100"
Gate oxide thickness (nm)	110	70	50	30	10
Smallest geometry (µm)	6	3.5	2.5	1.5	< 1.0
Power delay product (pJ)	2.5	1.0	0.5	0.25	
Gate delay (ns)	3.0	1.0	0.4	0.20	< 0.10

vices. We see here that

geometries of 0.9 um in

the first generation and

eration are expected. In

the first generation this

0.5 um in the second gen-

Propagation delay

L = 10 mm Length of circuit $V_{\rm s} = 1 \times 10^{10} \, {\rm cm/s}$ Propagation delay

Expostations for 1990 1996

Master product level		emory 2nd gen.		S logic 2nd gen.	Bip 1st gen.	
Width of structure	0.7 μm	0.3 μm	0.7 μm	0.3µm	0.9 μm	0.5 μm
Chip sizes	100 mm ²	< 200 mm ²	100 mm ²	200 mm ²		
Transistor functions	5 × 10 ⁶	108-109	106	108	105	107
Wiring levels	4	<6	<6	<10	<5	<8
Limit frequency					12 GHz	40 GHz
Access time	40 ns	<40 ns				
Data transmission rate	-				2.4 Gbit/s	10 Gbit/s

plications covered ap-

Point 3: GHz devices have already been developed with silicon Further possihilities will open up after 1000/05

Markets

Where then are the applications and markets for GaAs devices? The applications of GaAs are in those areas where on the one hand increased thermal resistivity, high resistance to radiation, and optical-electrical applications are called for These are physical properties in which GaAs is clearly superior to silicon or properties which silicon does not possess. This means that the main area of application for GaAs is the military sphere aviation and the aerospace industry. In 1984, these ap-

proximately 46 per cent of the market share of GaAs and it is expected that this market share will be extended to 56 per cent in 1992. These circuits will not be highly integrated cir. cuits In other words they will be MSI circuits rather than VISI circuits Alongside this area of anplication. GaAs is also expected to be used for small-scale integration circuits as interface circuits in the communication engineering industry for optical-electrical interfaces. The areas of application will require medium and small-scale integrated circuits, but not system integration with corresponding VLSI circuits. But then are the figures given at the beginning reliable, namely that the market potential for

GaAs in 1992 will be worth about 3.2 billion dollars? These figures are right according to the information available at present. They show that GaAs will only account for a small share of IC consumption, while silicon will continue to dominate and provide the basic material for largescale integration.

Conclusion

To sum up, we can say that GaAs will not become a substitute for silican in large-scale integration or in system integration. It will be possible to realize some individual functions better in GaAs than in sili. con. These functions, however, will have to be very critically examined as realizing certain functions in a different technology

always raises questions concerning interfaces For evample the position of the interface between silicon and GaAs in systems for optical communications will very much determine the success or failure of a new system Not only physical properties will necessarily play a decisive role in this but also the technological practicability of the whole system. The transition from a technology that is mastered to a new and relatively difficult technology always involves a large number of technical risks It may thus be a better prospect to use a familiar and perfected technology even perhaps at the cost of "technical elegance" and only to use the other technology where it is absolutely necessary for making a system more efficient and more rapid The choice of technology or the question of the interface between two technologies will thus be decisive for the success of complex systems. Realizing functions in GaAs which cannot be realized in silicon does not represent substitution Questions of this kind are of course excluded from any consider-

Phillips Report No. 10 750F (from a speech by Dr Peter Draheim, Valvo, Philips GmbH, Federal Germany)

ation of the auestion of

substitution

Quantity	Symbol	SI Unit	Abbr.	Quantity	Symbol	SI Unit	Abbr
electric current	1	ampere	A	reluctance	R. Rm	reciprocal henry	I/H
electric charge quan-	0	coulomb	C	permeance	A	henry	H
tity of electricity				phase displacement			
electric field strength	E	volt per metre	V/m	number of turns on			
potential difference	U	volt	V	winding	N		
electromotive force	E	volt	V				
electric flux	*	coulomb	C	impedance	2	ohm	Ω
capacitance	C	farad	F	reactance	X	ohm	Q
magnetic field strength	H	ampere per metre	A/m	quality factor	0		
magnetic potential	Um	ampere	A	admittance	Y	siemens	S
difference				susceptance	В	siemens	S
magnetomotive force	F. Fm	ampere	- A	active power	P	watt	W
magnetic flux density	8	tesla	T	apparent power	S. (Pg)	watt	W
magnetic flux	0	weber	Wb				(- V A
self inductance	1	henry	н	reactive power	Q. (Pq)	watt	W
mutual inductance	M. L12	henry	H	wavelength	1	metre	m
coupling coefficient	*			frequency	v. 1	hertz	Hz
velocity of light in a	c	metre per second	m/s	angular frequency	ω ^r	hertz	Hz
vacuum				period	T	second	5
resistance	A	ohm	Ω	time constant	r	second	8
resistivity	P	ohm metre	Ωm	thermodynamic	T	kelvin	K
conductance	G	siemens	S	temperature			
conductivity	k, r.(0)	siemens per metre	S/m	energy	E	joule	J

DARK-ROOM EXPOSURE

METER

No photographer can work properly in his dark-room without some sort of light meter. The instrument proposed here is not expensive, easy to build, and, apart from the exposure time, it indicates the contrast in relative light values.



In spite of its simplicity, the meter is accurate enough for virtually inequirements. Moreover, it is constructed from standard components throughout, with the possible exception of the Type BPW21 photodock. Operation of the meter is simplicity itself: a push button for normal exposure measurement, another push button for constrast measurement; and a microammeter for the read-out.

Circuit description

The first notable aspect of the circuit diagram in Fig. 1s that three different levels of supply voltage are required + 2V + 5V and + 9 V. Aft first sight this may seem extravagant, but its not really as will be seen later. Moreover, the three levels are obtained relatively easily. The +9 V is provided direct by the battery, since the total current consumption does a considered pPd will do nicely. The +5 V surply is derived from the bat-4V surply is derived from the bat-4V surply is derived from the bat-4V surply is derived from the bat-

tery via a Type 7805 voltage regulator, while the +2 V supply is provided by a voltage divider (R₁₀-R₂₀) and an opamp (IC₅).

The exposure meter is based on a

Inle exposure meter is based on a well-known principle: the photo-voltaic effect. This effect causes certain semiconductor diodes do produce a forward voltage when they are illuminated. This voltage changes in direct proportion to the logarithm of the causative change in light flux, provided the clicde is use minated in a high impedance. This provise is med in the present circuit by terminating the photoclode. By terminating the photoclode.

It should be noted that the spectral sensitivity of the BPW21 is very similar to that of the human eye. The maximum sensitivity of the diode and the human eye are about the same, but the BPW21 has a somewhat larger bandwidth.

The diode voltage is amplified and inverted in three opamps: IC2; IC3; and IC4, and then applied to the series combination of the meter, M₁.

resistor R₁₀, and preset P₂ In this application, the meter should have a logarithmic scale (see Fig. 2). It should be noted that this exposure

meter works in an exactly opposite way from that in a camera, because way from that in a camera, because the present meter should not indicate the amount of light, but the required period of illumination. Therefore, when the light flux is large, the diode voltage is high, and the voltage across the meter is low. Conversely, if there is but little light, the meter will deflect strongly. Plodes D. and D. seave to compen-

sate for the variation of the diode voltage with temperature. In the prototype the variation resulted invadifference of only half a stop for every 7°-CC: a perfectly satisfactory value, the more so when it is remembered that the temperature in a datricom must be kepf fairly constant. As long as the three diodes are not strument is handled, all will be well. Potentionneter P₁ affords compensation for different paper sensitivities. because in conjunction with R.R. Ro-Ra-Da-De it can add a small direct unitage to the measured unitage Since the meter scale is logarithmic this added voltage manifests itself as a multiplication of the indicated time The effect of Pa is the same as that of D. but this control is only set during the initial calibration of the inctrument

Contract messurement is effected with the aid of electronic ewitches FS. FS. and FS. When the contract push button So is open ES; will also he onen while FS, and FS, will he closed (cituation as shown in Fig. 1). The circuit operates as an exposure meter as described. In this state a light section of a negative should be massurad

When So is pressed ESo and ESo onen and ES; will close for a short time (at the instant-after ES, has opened-that Cs is charged via R13 and Rea junction Cs-Rea will go high. which causes ES, to close; once Cs is charged junction Cs-Rs will go low and this causes ES, to onen again) During the time that ES, is closed. Ca is charged to the potential then present at the output of ICs. The voltage across the microammeter then drops to zero, so that the pointer does not deflect at all. Even when ES: opens again after a short while the potential across C4 is maintained

With So still depressed hold the photodiode under a dark part of the negative: the meter will deflect again, but the voltage across Ca is now deducted from the measured value In other words the meter now indicates the contrast (in LV) between the first and second measurements ie between the light and dark parts of the negative Since a difference of one IV flight

value) corresponds to a doubling (or halving) of the light flux, the contrast scale of the meter is calibrated linearly as shown in Fig. 2.

Construction

The circuit is best constructed on a small piece of single-sided Veroboard. As far as the enclosure is concerned, any small one will do, as long as the board, microammeter. and operating controls can be fitted neatly. The controls should, of course, be easy to reach and operate. The photodiode should be

D2 D5 - 1N4148 ü ES1_ES3 = % IC1 = 4066 (+) 5V

mounted in a manner which ensures that the light from the enlarger reaches it freely. Diodes Do and Do should be placed as close as possible to the photodiode, so as to keep temperature differences between the three as small as possible.

Setting up

Set P1 to the centre of its travel. Using photographic paper of average sensitivity, make a test strip that is correctly exposed with an exposure time of 2 seconds. The lowest stop number should be used, and the correct illumination obtained by adjusting the height of the enlarger. Place the exposure meter on the base of the enlarger and disperse the light for instance by holding a piece of opaque paper in front of the

Adjust P2 until the microammeter indicates 2 s.

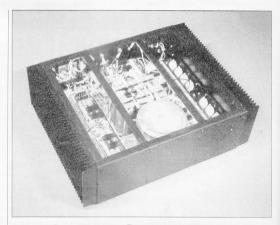
Select the fourth lowest f-stop and adjust Pa until the microammeter reads 32 s (=contrast of 4 LV).

Finally

A calibrated scale needs to be made for P₁ corresponding to the sensitivities of different types of photographic paper. This requires the making of a lot of test strips, but such a scale will be found very useful in practice for a long time to come.

For contrast measurements, the position of P1 is irrelevant (as long as it is not changed between the two measurements).





HIGH-POWER AF AMPLIFIER — 2

After last month's discussion of the power output boards and associated power supply, this concluding article details the design and construction of the bridge/stereo preamplifier, driver stage power supply, soft turn-on and protective circuitry, as well as an effective fan control section. In addition, a variety of illustrative material is offered as an aid to understanding the amplifier's mechanical construction.

Driver stage power supply

The circuit diagram of the combined ±90 V and ±12 V supply unit originally given in June issue of Elektor India. unfortunately contains a small error and a correct version of it is, therefore, reproduced here. The ±90 V driver stage supply is quite straightforward; it is capable of

supplying up to 2×100 mA. The open-circuit voltage of this section is about ±100 V. The ±12 V supply is so conventional as to make any description of it unnecessary.

Preamplifier

In order that the amplifier can be switched from 2×250/500 W stereo to 1000 W mono operation in a

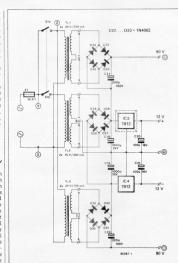
bridge-connected configuration, the two power output boards must be driven with the normal left and right signals (store) or complementary phase signals (bridge set-up), both configurations are supported by the special preampilifer shown in Fig. 8. It can be seen that the antiphase signals come from opamps As and inverting, the later as an inverting amplifier stage. In order to ensure simultaneous clipinin (levels and identical overall response for both power output boards, all resistors the circuit must be 1% tolerance, high stability metal film types. The preamplifier inputs are balanced, so that the amplifier can be driven direct from low-noise, balanced cables, as is customary in large PA

Nowever, where unbalanced inputs are preferred, the negative input terminals may simply be grounded. Stereo potentiometer P: should be a high quality type, since any tracking error may readily lead to differences in output power from the amplifier's left and right channel. In some cases, a linear stereo potentiometer may, therefore, be preferable over a logarithmic type.

Soft turn-on and protective circuitry

The power-on delay circuit, shown in Fig. 9 has its own DC supply which operates off the AC2 voltage from Tro When the mains switch is closed. C7 is charged rapidly, and Ca provides an approximately one second long high logic level at the inputs of Ni whose inverted output lovel disables To Therefore Rev will not be energized until one second or so after power-on, and the initial turn-on current for Tra and Tra is forced to flow through "brake" resistor Rss. whose function has already been explained in last month's article on the high-power AF amplifier - refer to Fig. 5 and the section on power supplies in that article After the initial second has lapsed. Rse is short circuited by the Rei contact, and Tr4 and Trs receive the full mains voltage across the primary windings. The red LED goes out, and the vellow one lights to indicate the second interval of 1.5 seconds before Co is charged. No supplies a low and N4 a high logic level, and Rez is energized, connecting the loudspeakers to the amplifier outputs: at which moment the vellow LED goes out and the green one lights, indicating that the amplifier is fully operational. The outlined power-on timing sequence prevents blown fuses as well as loudspeaker

destruction. When the amplifier is switched off, the voltage across Cr is the first to break down, since this smoothing capacitor is rated at only 100 µF. The resulting low logic level at the sectivate Res. disconnecting the loudspeakers from the amplifier outputs. At the same time, Re is deactivate in the section of the law of



Parts list for the combined ±90 and ±12 V

Capacitors: (electrolytic) C18; C19 = 1000 μ; 25 V C20; C21 = 100 μ; 16 V C22; C23 = 220 μ; 100 V

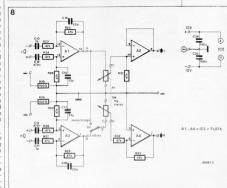
Semiconductors: D22...D33 = 1N4003 IC3 = 7812 IC4 = 7912

Miscellaneous

F1 = 10 A fuse; slow. Fuseholder for panel mounting. S1 = double pole mains switch 3A.250 V. Tr1;Tr3 = 2 × 24 V; 150 mA. Tr2 = 2 × 15 V;400 mA. T0220-style heatsink for

Relevant section on PCB Type 86067 Soldering pins and wire as required. Three-pin mains chassis plug rated at 240 V AC; 10 A.

Fig. 8. Circuit diagram of the switchable stereo/bridge preamplifier. Connect the — input terminals to ground to suit operation with unbalanced drive signals.



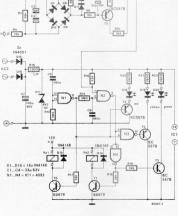
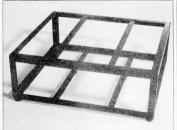


Fig. 9. Combined circuit diagram of the output DC monitor and the sequentially controlled relay drivers for loudspeakers and ±78 V



has dropped. All LEDs go out, but the large capacitance of the ±75 V supply ensures the protonged presence of a slowly falling supply voltage for the amplifier output stages, so that the loudspeakers are protected against cilcks at power-off. The relays used in this design should be outpalled of switching and sustaining high contact currents, both Rei and Rei should be raied at least 10 A in this respect, and suitable types where the party of the party list with

The proposed circuit with T: and T: keeps tabs on the presence of any dangerously high direct voltage levels at the amplifier outputs. Should anything be amiss in this respect, the input of Ns is pulled logic low and Res is consequently deactivated. The green LED goes out and the yellow one lights in order to signal the fault condition.

Fan control

A powerful fan capable of helping to keep the heat sink temperature within reasonable limits is an indispensable item in case the amplifier is to output continuous high power levels, such as may be required in applications involving multi-loud-speaker set-ups to cater for considerable sound pressure levels (SPI) at large sites.

Depending on the task assigned to the amplifier, the fan control circuit shown in Fig. 10 may be constructed single or two times over (one or two fans, as required).

If a single fan is used, both Ts and Ts are required as temperature sensor devices, because it is preferable to monitor both heat sinks simultaneously. Do not forget to fit these sensors with insulating washers. bushes and heat conducting paste. Two fans require two control circuits. and To can be dispensed with in each of these: a single sensor Ts suffices. Operation of the fan control circuit is straightforward; the Type BD139 transistors function as heatsink-mounted temperature sensors. Given an ambient temperature of 20 °C and a collector current as defined with Rss, the base-emitter voltage (Ube) of the Type BD139 is typically about 625 mV. The fact that base of the sensor transistor is arthat P2 has been set to a base voltage will not conduct until its Upe has dropped to 855 mV, in other words, when the transistor junction temperature has risen to 50 °C. At this point, Te is driven and the fan is switched on via the Res contact. This switched on via the Res contact This condition is signalled by LED Du, which should have a suitable colour so as to be readily spotted from a distance. Resistor Riv effects positive feedback which ensures a lysteresis of about 5°C, no transistor of about 5°C, to the contact the contact of the

A common PCB

All of the discussed circuits are fitted on a single PCB as shown in Fig. 11 with the exception of transformers Tr., Tr., Tr., the relays, Ts and Ts (the latter as required in the specific faan arrangement). Where this is desirable, the ready-made PCB for this project may be out into sections for mounting in suitable locations in the amplifer cohing

Fitting the parts should not present problems; the constructor need merely decide on the number of fans and associated control circuits; either one, two, or none.

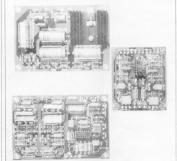
Amplifier construction and wiring

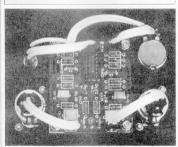
The unit configuration shown in Fig. 12 may be studied and copied in case the amplifier is to operate without fans. It can be seen that the large heat sinks form the sides of the cabinet, the location ensures sufficient cooling for relatively low power use of the amplifier.

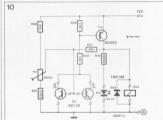
However, heavy duty applications require the use of a special combination of heat sink and fan as illustrated in Fig. 18. Note the cooling fins at the inside of the tube-like construction, at one side of which the fan has been mounted to provide a continuous stream of fresh air passing along the inside surface of the tunnel

All supply, relay and loudspeaker wiring in the amplifier should be made with heavy-duty stranded wire having a cross-sectional area of 2.5 mm² or more.

It would seem advisable to start the wiring job with the connection of the low power transformers Tr... Tr., refer to the relevant diagram and note the use of the separate switch section Sa for Tr., Now connect the driver supply board and verify the presence of about ±100 V (open-circuit voltage) and ±12 V. Discharge the smoothing canactions via 10 k







able and dimensioned to suit individual requirements as to the number of fans, this sensor-driven control circuit safeguards against heatsink temperatures that endanger the life of the power MOSFEIS in the amplifier output

Preamplifier (Fig. 8).*

Resistors: R23...R33 = 47 k;1% * R34;R35 = 100 Q P1 = 10 k potentiometer; logarithmic*

Canacitors

Parts list

C10;C11 = 1 µ;MKT C12;C13 = 470 n C14...C17 = 22 p C24:C25 = 100 n

Semiconductor:

Miscellaneous: S2= single-pole toggle switch Relevant section on

PCB Type 86067 Soldering pins as required 2 off 3-way Cannon/XLR plugs * see text

> Parts list DC monitor and power

DC monitor and pow on delay (Fig. 9). Resistors:

R3... R6 = 56 k R7;R8 = 10 k R9;R10 = 3k9 R11;R12 = 1k8 R13 = 2M2 R14 = 3M3 R15 = 220 Q;0.5 W R16 = 22 k R17;R18 = 39 k R19 = 56 k R22 = 390 Q

Capacitors: C1...C4=33 μ;6: electrolytic C5;C6=22 μ;16 \ electrolytic

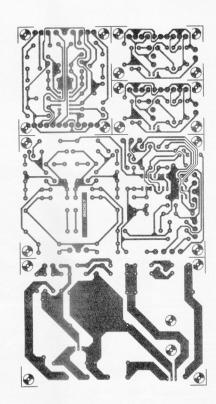
electrolytic
C7 = 100 \(\mu, \)35 V;
electrolytic
C8; C9 = 560 n

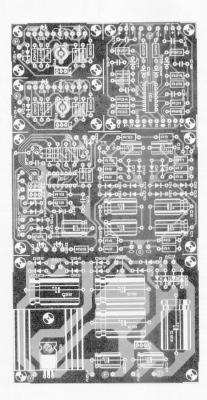
Semiconductors:

Semiconoucloss.

D1., D14 = 1N4148
D15;D16 = 1N4001
D17 = zener diode
8V2;1.3 W
D18 = LED; red
D19 = LED; yellow
D20 = LED; green
T1., T3 = 8C5478
T4;T5 = 8C5578
T6;T7 = 8D679
[C1 = 4083

Miscellaneous:
Re1 = high power relay,
coil voltage 12 V;
single contact, rated at
10 A-240 V
(e.g. Schrack Type
RL200012; base Type





Rez= high power rescoil voltage 12 V; 2-pole change-over, contacts rated at 16 A-80 V (e.g. Schrack Type RX020012). Relevant section on PCB Type 86067 Soldering pins as

> vailable from STC lectronic Services, elephone 0279) 26777.

Parts list Fan control (Fig. 10).

Resistors: R36 = 3k9 R37 = 120 Ω R38;R39 = 3k3 R40 = 560 Ω R41 = 68 k P2 = 100 Ω; preset Semiconductors: D21 = LED* D34 = 1N4148 T8;T9 = BD139 T10 = BD680

Miscellaneous: Rg3 = 12 V relay, contact rating 240 V AC: 1 A. Axial fan(s) as require (e.g. EBM Type WZS075-AA13-02; STC Electronic Services, telephone (0279) 267771*. Soldering pins as required.

required.
Relevant section(s) on
PCB Type 86067
Insulating washers an
bushes as required for
T8 and T9
* see text

Fig. 11. Component mounting plan for the com bination of sup port circuits to the power output

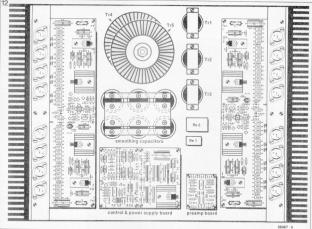
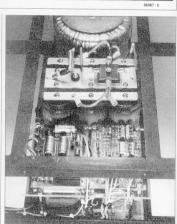


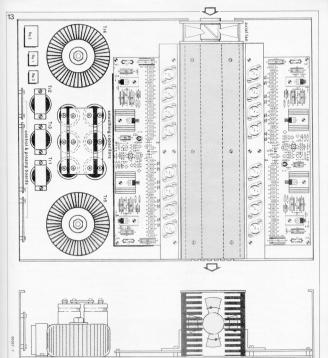
Fig. 12.
Suggested configuration for the amplifier if it is intended for relatively low-power applications, e.g. stereo operation at 2×250 W into 8 ohms.

I W resistors, before proceeding with the connection of the power-on delay and protective circuitry. Note the ground connection on the power-on circuit; it should be run direct to the centre tap of Tra to prevent the I0 ms charge pulse for Cr from causing hum on the supply lines to the preamblifer

may now be tested: switch on the mains and verify the delayed action of Rei and Reg in that order Applying a direct voltage, e.g. the + or -12 V supply rail, to either one of the protection DC sense inputs L or R should immediately deactivate loudspeaker relay Re2; the ground terminals for delay and DC sense circuits should be temporarily connected for this test. When wiring the L and R inputs to the loudspeaker lines, remember to make the connections direct to the amplifier outputs, that is, not behind the Rea contacts!

The construction is next proceeded with the wiring around the toroidal power transformers T^* and T^* s, taking due care not to confuse the X_i Y_i and Z_i points. Brake resistor R^{sig} should be mounted on a set of soldering tags. Also remember to fit all mains wiring in an absolutely safe





and sound manner, so as to prevent possible lethal contact with any of

A common earth point should be created at the ground terminal of the ±178 V power supply, and this point should serve as the common earth return terminal for the loudspeaker wires in the stereo set-up, as well as the point from which the earth return (o) wire to the amplifier boards is run. Since this wire does not carry high currents, it need not be as thick as those for the ±75V rails. The



Fig. 13.
Suggested hea.
sink arrangement for heavy
duty amplifier
use

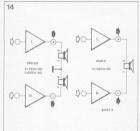


Fig. 14. Connection diagrams showing stereo and bridge configurations at the amplifier outputs. Note that the minimum loud-speaker impedance in the bridge set-up is 8 ohms, and refer to the text for details on the loudspeaker polarities.

ground terminals on the power amplifier boards, marked a are next wired to the corresponding terminal on the driver supply board. Since this point is also the ground terminal for the preamplifier board, the signal wires between drivers and preamplifier should have their screens connected at the preamplifier fer end only.

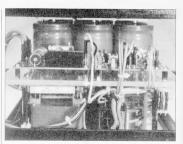
The preamplifier ground input connections should be isolated with respect to the amplifier enclosure, and it is best to purchase two Type XLR connectors for this purpose (see parts list).

The amplifier's metal enclosure is connected direct to the mains earth line, as well as to the central ground terminal on the ±75 V supply, using \$100.0 register.

Finally, the construction of the highpower AF amplifier is illustrated with a number of photographs in this article, offering suggestions regarding possible enclosure construction and wiring methods (note the purpose-weided framework to hold the CPBs and heavy parts). Keep in mind CPBs and heavy parts). Keep in mind the purpose weight of the purpose weight tion is paramount to reliability and the ability to resist the kind of rough treatment an amplifier of this type is likely to be forced to endure.

Testing

After the amplifier has been completed, it is time to check its correct operation. In case you have been patient enough not to test the power output boards as yet, start off with replacing the 6.3 Å fuses with 22 c 1 W resistors, and turn the quiescent current presets (P) fully anticlockwise. After switching on the amplifier on voltage should be measured across these fuses substitutes. Should the



loudspeaker relay remain off after the power-on delay, there is bound to be something amiss in the MOSFET output stage. Now check all supply voltages in the amplifier before proceeding with setting the quiescent current to 400 mÅ per 78 V supply to 100 mÅ per transistor). The voltage levels given in circuit diagram Fig. 3 may now be checked, at the same time pay due attention to equal current distribution among the power MOSFETS, i.e. each group of parallel-connected source resistors should drop about 26 mV. Large differences in this respect may cause some of the transistors to provide all the level of the load, while others are left.

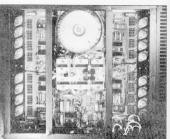
Leave the amplifier switched on for some time to verify its thermal stability under quiescent current conditions. The remainder of the test procedure includes checking the output power capability and distor-

tion-free amplification within the frequency bands and signal level range given in the feature list of article (See Elektor India June 86)

There is one tinal point to make concoming the loudspeaker polarity in the stereo set-up (Fig. 1½; note the reversed polarity of the loudspeaker at the R output; this is the result of the 180° phase turn occurring in the reverting opamp in the preamplifier. However, if the wiring to the loudspeaker output sockets is made as shown in Fig. 14, this oddity need not concern the user once the amplifier is fully operational.

Finally, the bridge configuration requires the amplifier to be driven monaurally at the left-hand channel input.

TS;TW



When a multimeter is used for measurement, there can he two types of errors genuine measuring errors and errors which are not coally measuring arrorel Even the specified technical data for electronic companents allows for dovistions as high as 10% The carbon film registors show tolerance values of +5% or +10% Canacitors with ± 10% tolerance are considered to be very good Transistors are tested after manufacture and classified according to their current amplification factor. This classification is designated by a letter or a number appearing after the type number of the transistor i e BC147B). Inspite of this classification the values of the current amplification factor within a

change with time.

Nevertheless, most of the circuits function correctly in spite of considerable component tolerances.

Where accuracy is required, suitable compensations must be provided.

group deviate from each

case of components like

electrolytic capacitors, the

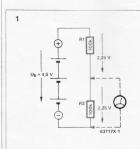
specified values may also

other by more than +30%. In

Whenever we find that a measured value deviates from a specified value, we must first see if this is due.

Measuring Techniques

Chanter 3



to composent tolerance. We must also consider whether the deviation has an effect on the functioning of the particular circuit. It is not possible to make any generalised statement about the effect of such deviations on the circuit performance, because the deviations vary from component to component and the effect is different for different of different of different means to the component and the effect is different for different fo

Let us take an example to see how a genuine measuring error can occur irrespective of the actual measuring accuracy of the measuring instrument.

measuring instrument. Figure 1. shows a voltage divider made of two $100K\Omega$ resistors and a 4.5V battery connected across the

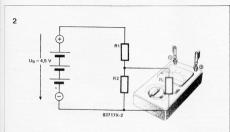


Figure 1: A potential divider made of two equal resistors of 100KΩ each. The expected voltage across R2 is 2.25

Figure 2: When a multimeter is connected to measure the voltage across R2, its internal resistance R is effectively connected in parallel with R2 and thus affects the equivalent resistance across which the voltage gets measured.

selex

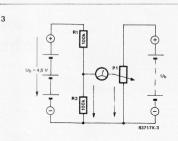
combination Theoratically these two resistors must divide the battery voltage of 4 5V into 2 25 + 2 25 Now let us connect a multimeter across R2 and measure the voltage across R2 Surprisingly it is only 1 8V The cause of this measuring arres in the aureant drawn by the multimeter itself This current is the result of the internal resistance of the multimeter. This value can be calculated from the Ohme per Volt enecification of the multimeter. The internal posistance is obtained by multiplying the ohme per Volt value by the measuring range in volts Thus a multimeter with 20KO per Volt being used on 10 V range will give the internal resistance Ri as follows :

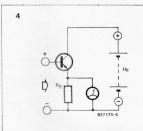
B: - 10V x 20K 0 /y = 200 K 0

As this is affectively connected in parallel with the 100KO registance in our above example, the equivalent resistance becomes 67KΩ. The notential divider thus becomes a combination of 100KO + 67KO. The voltage acrose R2 thus becomes 1-8 instead of 2.25. The voltage being measured is really 1.8V as shown by the multimeter. The voltage across R2 changes due to the presence of multimeter and the measured value is falsified

To get over this difficulty the meter can be connected as shown in figure 3. The voltage across R2 is not measured directly, but compared with another voltage across the potentiometer P1. The difference in voltages will be shown by the multimeter. and will become zero when the two voltages are equal. The meter does not draw any current in this condition as voltages on both the terminals are equal.

The potentiometer can have a directly calibrated dial to read the voltage, or we can now measure the voltage





across the sliding contact of P1 independantly. If the total value of P1 is kept low enough, the internal resistance of the multimeter will not affect the reading Another way to get rid of this problem is to use a high impedance input circuit with the multimeter. The schematic diagram of such a circuit is shown in figure 4. The impedance converter contains an amplifier which requires a very low input current and gives a high output current which is

proportional to the input

current. An emitter follower circuit can be used in case of ordinary transistors, and a source follower circuit can be used in case of FETs. The input voltage is not amplified by the amplifier and thus the measured voltage is indicated accurately by the multimeter without drawing input current from the voltage under test. Effectively, the Ri of the multimeter can be said to have become very high. In case of an emitter follower.

the theoretical value can be

Figure 3: No current can flow through the meter when voltages on both terminals become equal to each other. The meter indicates zero at this point. As the meter does not load the test circuit, the voltage values are not affected by internal resistance of the meter.

The high impedance attachment for a multimeter using an emitter follower emplifier. The amplifier draws negligible current and does not load test circuit.

estimated as follows. The effective Bi is the product of the current amplification factor of the transistor and the parallel combination of Re and Ri of the multimeter. As RE is much smaller than Ri, we can have Ri (effective) = RF x Current Gain. Assuming that RE = 4.7 KΩand current gain = 250, the effective input impedance Ri = 1.18 MΩ. Thus the multimeter can now he said to have an input resistance of about 1MO which is sufficiently high for most measuring applications.

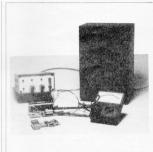
Measuring Power With A Multimeter

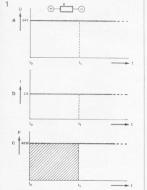
The ability to convert a specific quantity of energy in a specific period into another form of energy is called power. Speaking in electrical terms we can say

p (t) = u (t), i (t)
where p(t) is electrical
power, u(t) is voltage and i(t)
is current. In case of DC
currents and voltages the
relation becomes

Capital letters are used for DC quantities which are not a function of time, that is, they do not change with time. Lower case letters are used for Alternating quantities, and to show their dependance on time they are written as p(t), u(t), i(t) etc.

Let us first look at the DC quantities. Figure 1 shows U, I and P as steady levels (DC quantities). The current





I flows through a resistance R and the voltage across that resistance is U. All these values do not change with time and hence at any given time the following relation holds good;

P = U.I Now for example let U = 24V, I=2A then we have the

P = 24V × 2A = 48W
Here the W stands for
Watts, which is the unit of
the so called DC power. You
must have noticed by now
that measuring DC power
with a multimeter is very
simple! Just measure the
current and then multiply
them to get the DC power.

Figure 1 :

The values of DC voltage (a) and DC current (b) are constant at every instant. Hence the product (c) is also constant at every instant. The shaded area in (c) represents the energy which is converted into heat in the resistance R

selex

Now let us consider the other possibility. The voltage and current can be alternaing values, as shown in figure 2

We can come across such type of quantities in case of an output stage of an amplifier. The output stage produces an alternating

Can we use the multimeter to measure the power even in this case? Though the answer is Yes, it is not as simple as in case of the DC quantities.

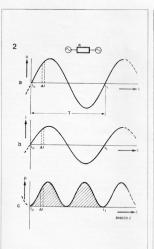
Let us have another look at figure 2. Here an alternating current i flows through a resistance R and the voltage across the resistance is II which is also an alternating voltage Naturally so, because the recietance has a fived value of B ohms. The nature of waveforms for II and I are both eine wayee These are known as sinusoidal waveforms. They are veriable with respect to time and said to be functions of time If we take the value of u and i at any given instant of time and multiply them together, we can get the nower at that instant of time. This process can be carried out at every point on the time axis and the resulting power, which will also be a function of time can be plotted as in

figure 2 C. The power can also be expressed as an average over a period T. For this nurpose the average value converter can be used as shown in figure 3 Using such converter it is nossible to obtain average voltage and current and then multiply them to get average nower However this does not give the active power or the effective nower. Also, please note that what we mean hy average current and voltage is not the true average hecause average current and voltage of a sinusoidal alternating waveform would he zero! The average we are talking about is after the full wave rectification by the

bridge rectifier.

Why the active power or the effective power alone is a true measure for the power can be explained with help of the set up shown in figure 4. Here we see the output stage of a Hi-Fi amplifier connected to a loudspeaker and a loudspeaker and a

Now consider an alternating current flowing through the speech coil of the loudspeaker. Not only the membrane of the loudspeaker moves to and fro, the alternating current produces heat in the speech coil of the loudspeaker, because it also has an



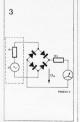


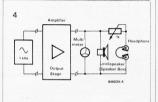
Figure 2

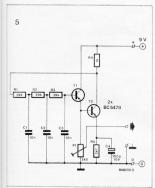
rigure 2: If a sinusoidal voltage (a) is applied to a resistance, then a sinusoidal current (b) is generated through the resistor. The power calculated at consecutive points can be plotted as in (c).

Figure 3:

The average value converter consists of a full wave rectifier bridge connected to a moving coil meter. The moving coil meter effectively averages out the input voltage.

Figure 4:
The measuring set up for measuring power with a multimeter. A practical set up is shown in the photograph in the beginning of this chapter.





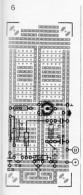


Figure 5: Sinusoidal signal generator for 1KHz. Figure 6: Component layout of the circuit in figure 5.

Component List:

81 to R3 = 39KΩ
R4 = 1KΩ
R5 = 2.7 KΩ
P1 = 2.5K L17 im Pot.
C1 to C3 = 10 nF
C4 = 100 uF/10V
T1, T2 = BC 547 B
1 Standard SELEX PCB
1 5V Battery Pack.

Ohmic resistance. The same quantity of heat could also he produced by a direct current This particular value of direct current is called the effective current The effective current is greater than the average value by 11% For example the mains supply voltage is 230V Jeffective value where as the average value is only about 207V If we connect the multimeter across the mains outlet it reads 230V because it is designed to read the offostivo valuo in the AC ranges. The scale of the multimeter is calibrated in such a manner that it directly reads the effective value for a sinusoidal alternating input. This is well suited for our

The effective values of current and voltages are also called RMS values Without going into the details we can just note that RMS stands for Root-Mean-Square This notation comes from the fact that for a sinusoidal alternating waveform the effective value is the square root of the mean of the squares Heing the effective (or RMS) values of voltages and currents, the same formula. that is used for DC quantities becomes valid once again.

requirement of nower

P = U.I

This can be further simplified by using the Ohm's law

I = U/R

Thus the power equation becomes

 $P = U^2/R$

From this relation, the power measurement becomes still more easier, because we need only one measurement - that of the voltage across the loudspeaker, Resistance (impedance) of the loudspeaker is specified on the loudspeaker as either 810, 40 or 2Ω.

All we have to do is measure the voltage square it and divide it by the loudsneaker impedance. For example if we read 4.5V acrose the loudeneaker and if the loudeneaker has 80 impedance then the effective power is 2.53W Those measurements are carried out at a standard input frequency of 1KHz as can be seen from figure 4 The measurement however will depend on the amplifier cotting

What is of real interest is the non-distorted nower output. To decide this, it is hetter to helieve in one's own ears. A headphone can be connected as shown in figure 4 to check for exact setting of the amplifier volume control where distortion just sets in. The voltage can be measured at this setting and then from the loudsneaker impedance the non-distorted nower output can be calculated. The 1KHz sinewaye generator can be

constructed as shown in figure 5 and 6. Component list is also provided for the circuit. For the same output voltage the effective power output depends on the loudspeaker impedance. This can be confirmed by setting the sinewave generator and the amplifier for an output voltage of 4.5V and then changing the loudspeakers from 80 to 40 and then to 20. The 80. loudspeaker has about 2.5W, the 4Ω loudspeaker has about 5W and 2 O loudspeaker has about 10W. If the amplifier is not rated for 10W output.

distortion will set in with a

2Ω loudspeaker.

Power Calculations

The most important formula used in nower calculations

D - 111

which means that electrical power is the product of current and voltage. Another thing that becomes clear from this relation is that voltage or current alone is not sufficient to deliver any power output. A very common example of this is the crackling noise we sometimes hear while taking off a synthetic pulloyer This noise is generated by the minute sparks generated by the static electricity. The voltages involved can be as high as 10KV. However these sparks do not harm us as the currents produced are negligible.

The power is measured in Watts, and a Watt is defined as follows:

1W = 1V 1A If any two of the three quantities in the power equation are known, the third can be calculated.

Let us take an example. A bicycle dynamo produces unto 3W at 6V. So the current produced by the

I = P/II = 3/6 = 0.5A

Half an Ampere is not a very high current but it serves the purpose of lighting 3W bulbs at 6V! Here the voltage and current are both small and produce a small power output. However if we take the same current (0.5A) from out mains supply of 230V, the power output produced will be (230V) . (0.5A) = 115W

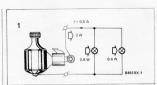


Table 1

1 pW = 0.000 000 000 001 W 1 Picowett 1 µW = 0,000 000 W 1 mW = 0.001 W

1 PM = 1000 W 1 MW = 1 000 000 W

1 GW = 1 000 000 000 W

1 Millisante 1 Kilowatt

1 Megawatt 1 Gigawatt

which is a substantial value. The difference is due to the higher voltage. From this we can clearly see that voltage and current both play an equally important role in producing power. Let us consider a practical situation A 100W bulb connected to mains suply of 230V. Its current can be

I = P/U = 100/230 = 0.43A

And using the Ohm's law for calculating the resistance, we have

- = 535 Ω R = 0 45 A

calculated as

This must be the resistance of the bulb. Surprisingly, a measurement of the bulb resistance with a multimeter gives a very low reading: about 30 to 400. What went wrong? our calculations, or the multimeter? Both of them are correct, and the





difference in two values can he explained by the fact that substant mongured with a multimotor was the recietance of the cold element and what we enlaulated was the reciptance of the hot alament when hulh is glowing. When the bulb glows there is a strong movement of electrons incide the allowing wire and the effective resistance increases Unfortunately the maine voltage remains same even when the cold bulb is switched on across the mains supply. This gives rise to a very high initial current given by

1 = 11/R = - = 76A

This initial current flowing into the bulb lights the bulb and the element is instantly heated up. The resistance then increases to about 5350 as seen before. The initial power drawn by the bulb is enormous

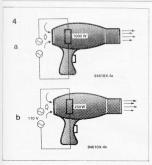
P = (230V) . (7.6A) - 1748 W

= 1.75 KW

The bicycle dynamo produces 3W electrical power at 6V output. This gives a current output of 0.5A

Figure 2 Although the 100W bulb requires less current than that produced by a hicycle dynamo, its power is much higher because the mains supply voltage is much higher than the dynamo voltage. Figure 3:

When a 100W a bulb is switched on it takes an instantaneous nower of about 1.75 KW. For an old bulb this may prove to be fatal.



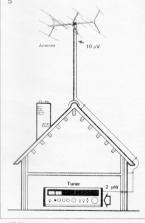
Fortunately this power is just the initial instantaneous power and drops down immediately to 100 W as the bull alows

l et us take another example to see how the supply voltage affects the power output to the same device Consider a 1000W Hair Dryer connected to 230V mains supply. The current

drawn is 4.3A The consumption of the fan motor is negligible compared to that of the heater. Now if we connect the same device to a supply voltage of 110V will the power also reduce to about half the value? No. the power

drons to one fourth the original value. As the voltage becomes half the current also becomes half and thus their product becomes one fourth. The Hair Drver now operates only at 250W

Let us now turn to some very low power devices. The antenna required by a radio is such a device. The antenna intercepts the radio waves and produces a tiny voltage of about 10 uV. This voltage drives an equally tiny current through the antenna cable and the receiver. If we assume the resistance to be of about 500, then the current is:



= 0.2 uA and the power delivered to the receiver is

(10uV) . (0.2uA) = 2pW That is two picowatt or two billionth of a Watt !

A 1000 W Hair Dryer works only at 250 W when the input voltage becomes half

Figure 5 Although radio transmitters operate at very high power values, what reaches the reception antenna is just a jew billionths of a Mass

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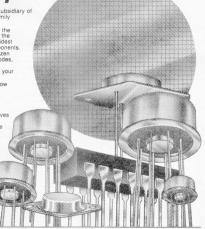
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CORRECTIONS

In verious cer theff alarms published in Elektor Electronics over the past very the alarm had the facility of incapacitating he ignition. See the properties of the properties of the been found that this can lead to damage to electronic ignition systerms, and in cars fitted with such a system, it is therefore better to use the relay that incapacitates the ignision system to break the supply to the starter motor (relay).

VHF Preamplifier

(May 1986 p-32) The value of capacitor C₆ should

Car burglar alarm

(Aug 1 Sept p. 67)
As drawn, the voltage across relay

RE₁ cannot drop to zero: it is, therefore, better to connect the emitter of T₁ to the +8 V line via an 18k resistor instead of to the collector of T₂.

Indoor unit for satellite TV reception - 1

(In This Issue)

 Owing to a processing error at the printer's, the lines between C₆ and MX₁ pin 1, and that between R₅ and the collector of T₂, have short, yet incorrect gaps. Als the T₄ base resistor is badly blurred; this is R₈, 10 k.

2. In the component overlay, Fig. 6, the resistor identified R₂ in the LO_L section should be R₂₀.

3. Please add to Fig. 5d: C = iso-



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